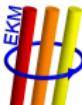


# From Quantum Mechanics to Materials Design

Volker Eyert

Center for Electronic Correlations and Magnetism  
Institute of Physics, University of Augsburg

October 14, 2010



# Outline

## 1 Quantum Mechanics

- Density Functional Theory
- Full-Potential ASW Method

## 2 „Materials Design“

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- Density Functional Theory
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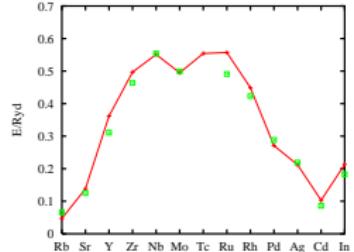
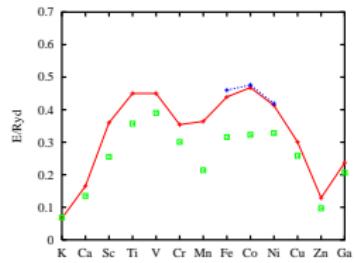
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- Full-Potential ASW Method

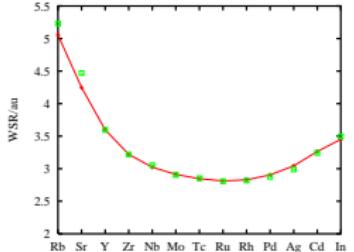
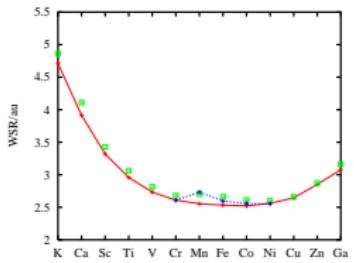
## 2 „Materials Design“

# Calculated Electronic Properties

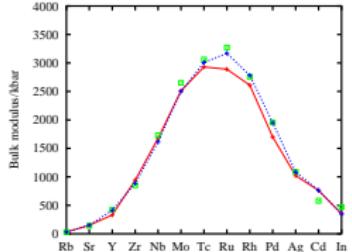
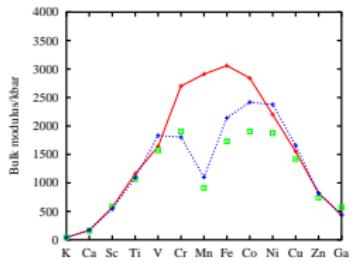
Moruzzi, Janak, Williams (IBM, 1978)



Cohesive Energies  
 $\hat{=}$  Stability



Wigner-Seitz-Rad.  
 $\hat{=}$  Volume

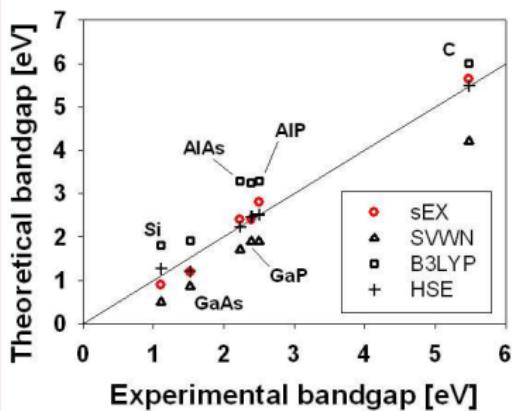


Compressibility  
 $\hat{=}$  Hardness



# Energy band structures from screened HF exchange

Si, AlP, AlAs, GaP, and GaAs



Experimental and  
theoretical bandgap  
properties

Shimazaki, Asai  
JCP **132**, 224105 (2010)



# Key Players

## Hamiltonian (within Born-Oppenheimer approximation)

$$\begin{aligned} H &= H_{\text{el,kin}} + H_{\text{el-el}} + H_{\text{ext}} \\ &= \sum_i \left[ -\frac{\hbar^2}{2m} \nabla_i^2 \right] + \frac{1}{2} \frac{e^2}{4\pi\epsilon_0} \sum_{\substack{i,j \\ j \neq i}} \frac{1}{|\mathbf{r}_i - \mathbf{r}_j|} + \sum_i v_{\text{ext}}(\mathbf{r}_i) \end{aligned}$$

where

$$\sum_i v_{\text{ext}}(\mathbf{r}_i) = \frac{1}{2} \frac{e^2}{4\pi\epsilon_0} \sum_{\substack{\mu,\nu \\ \mu \neq \nu}} \frac{Z_\mu Z_\nu}{|\mathbf{R}_\mu - \mathbf{R}_\nu|} - \frac{e^2}{4\pi\epsilon_0} \sum_\mu \sum_i \frac{Z_\mu}{|\mathbf{R}_\mu - \mathbf{r}_i|}$$

$\mu$ : ions with charge  $Z_\mu$ ,  $i$ : electrons

# Key Players

## Electron Density Operator

$$\hat{\rho}(\mathbf{r}) = \sum_{i=1}^N \delta(\mathbf{r} - \mathbf{r}_i) = \sum_{\alpha\beta} \chi_{\alpha}^{*}(\mathbf{r}) \chi_{\beta}(\mathbf{r}) \mathbf{a}_{\alpha}^{+} \mathbf{a}_{\beta}$$

$\chi_{\alpha}$ : single particle state



# Key Players

## Electron Density Operator

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$\chi_{\alpha}$ : single particle state

## Electron Density

$$\rho(\mathbf{r}) = \langle \Psi | \hat{\rho}(\mathbf{r}) | \Psi \rangle = \sum_{\alpha} |\chi_{\alpha}(\mathbf{r})|^2 n_{\alpha}$$

$|\Psi\rangle$ : many-body wave function,  $n_{\alpha}$ : occupation number

Normalization:  $N = \int d^3\mathbf{r} \rho(\mathbf{r})$

# Key Players

## Functionals

Universal Functional (**independent of ionic positions!**)

$$F = \langle \Psi | H_{el,kin} + H_{el-el} | \Psi \rangle$$

Functional due to External Potential:

$$\begin{aligned}\langle \Psi | H_{ext} | \Psi \rangle &= \langle \Psi | \sum_i v_{ext}(\mathbf{r}) \delta(\mathbf{r} - \mathbf{r}_i) | \Psi \rangle \\ &= \int d^3\mathbf{r} v_{ext}(\mathbf{r}) \rho(\mathbf{r})\end{aligned}$$

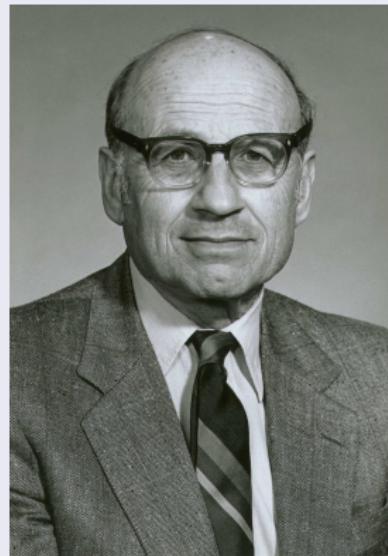


# Authors

Pierre C. Hohenberg



Walter Kohn



Lu Jeu Sham



# Hohenberg and Kohn, 1964: Theorems

## 1st Theorem

The external potential  $v_{ext}(\mathbf{r})$  is determined, apart from a trivial constant, by the electronic ground state density  $\rho(\mathbf{r})$ .

## 2nd Theorem

The total energy functional  $E[\rho]$  has a minimum equal to the ground state energy at the ground state density.



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## Nota bene

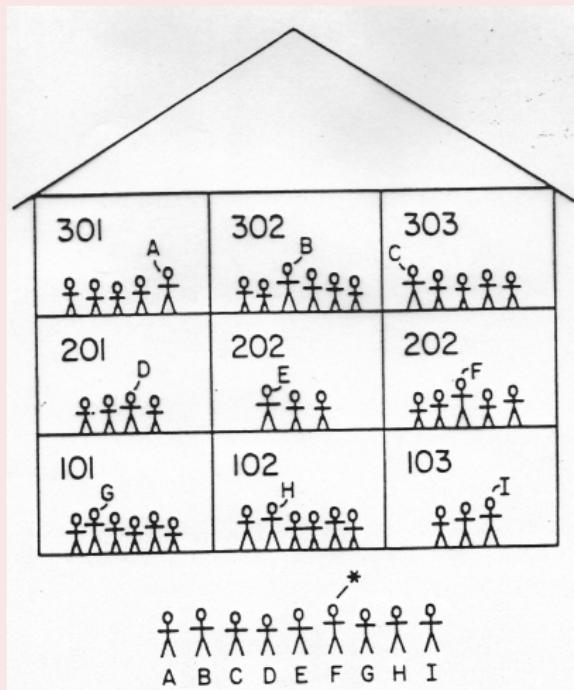
Both theorems are formulated for the ground state!

- Zero temperature!
- No excitations!



## Levy, Lieb, 1979-1983: Constrained Search

## Percus-Levy partition



## Levy, Lieb, 1979-1983: Constrained Search

## Variational principle

$$\begin{aligned}E_0 &= \inf_{|\Psi\rangle} \langle \Psi | H | \Psi \rangle \\&= \inf_{|\Psi\rangle} \langle \Psi | H_{el,kin} + H_{el-el} + H_{ext} | \Psi \rangle \\&= \inf_{\rho(\mathbf{r})} \left[ \inf_{|\Psi\rangle \in S(\rho)} \langle \Psi | H_{el,kin} + H_{el-el} | \Psi \rangle + \int d^3\mathbf{r} v_{ext}(\mathbf{r})\rho(\mathbf{r}) \right] \\&=: \inf_{\rho(\mathbf{r})} \left[ F_{LL}[\rho] + \int d^3\mathbf{r} v_{ext}(\mathbf{r})\rho(\mathbf{r}) \right] = \inf_{\rho(\mathbf{r})} E[\rho]\end{aligned}$$

$S(\rho)$ : set of all wave functions leading to density  $\rho$

$F_{LL}[\rho]$ : Levy-Lieb functional



## Levy, Lieb, 1979-1983: Constrained Search

## Levy-Lieb functional

$$\begin{aligned} F_{LL}[\rho] &= \inf_{|\Psi\rangle \in S(\rho)} \langle \Psi | H_{el,kin} + H_{el-el} | \Psi \rangle \\ &= \underbrace{T[\rho] + W_{xc}[\rho]}_{G[\rho]} + \frac{1}{2} \frac{e^2}{4\pi\epsilon_0} \int d^3r \int d^3r' \frac{\rho(\mathbf{r})\rho(\mathbf{r}')}{|\mathbf{r}-\mathbf{r}'|} \\ &= G[\rho] + \frac{1}{2} \frac{e^2}{4\pi\epsilon_0} \int d^3r \int d^3r' \frac{\rho(\mathbf{r})\rho(\mathbf{r}')}{|\mathbf{r}-\mathbf{r}'|} \end{aligned}$$

## Functionals

- Kinetic energy funct.:  $T[\rho]$  not known!
- Exchange-correlation energy funct.:  $W_{xc}[\rho]$  not known!
- Hartree energy funct.:  $\frac{1}{2} \frac{e^2}{4\pi\epsilon_0} \int d^3r \int d^3r' \frac{\rho(\mathbf{r})\rho(\mathbf{r}')}{|\mathbf{r}-\mathbf{r}'|}$  known!



# Kohn and Sham, 1965: Single-Particle Equations

## Ansatz

- ① use different splitting of the functional  $G[\rho]$

$$T[\rho] + W_{xc}[\rho] = G[\rho] \stackrel{!}{=} T_0[\rho] + E_{xc}[\rho]$$

- ② reintroduce single-particle wave functions

Imagine: non-interacting electrons with same density

- Density:  $\rho(\mathbf{r}) = \sum_{\alpha}^{occ} |\chi_{\alpha}(\mathbf{r})|^2$  known!
- Kinetic energy funct.:  
 $T_0[\rho] = \sum_{\alpha}^{occ} \int d^3\mathbf{r} \chi_{\alpha}^*(\mathbf{r}) \left[ -\frac{\hbar^2}{2m} \nabla^2 \right] \chi_{\alpha}(\mathbf{r})$  known!
- Exchange-correlation energy funct.:  $E_{xc}[\rho]$  not known!



# Kohn and Sham, 1965: Single-Particle Equations

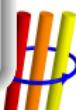
## Euler-Lagrange Equations (Kohn-Sham Equations)

$$\frac{\delta E[\rho]}{\delta \chi_\alpha^*(\mathbf{r})} - \varepsilon_\alpha \chi_\alpha(\mathbf{r}) = \left[ -\frac{\hbar^2}{2m} \nabla^2 + v_{\text{eff}}(\mathbf{r}) - \varepsilon_\alpha \right] \chi_\alpha(\mathbf{r}) \stackrel{!}{=} 0$$

- Effective potential:  $v_{\text{eff}}(\mathbf{r}) := v_{\text{ext}}(\mathbf{r}) + v_H(\mathbf{r}) + v_{xc}(\mathbf{r})$
- Exchange-correlation potential: not known!

$$v_{xc}(\mathbf{r}) := \frac{\delta E_{xc}[\rho]}{\delta \rho}$$

- „Single-particle energies“:  
 $\varepsilon_\alpha$  (Lagrange-parameters, orthonormalization)



# Kohn and Sham, 1965: Local Density Approximation

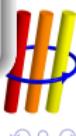
## Be Specific!

- Approximate exchange-correlation energy functional

$$E_{xc}[\rho] = \int \rho(\mathbf{r}) \varepsilon_{xc}(\rho(\mathbf{r})) d^3\mathbf{r}$$

- Exchange-correlation energy density  $\varepsilon_{xc}(\rho(\mathbf{r}))$ 
  - depends on **local** density only!
  - is calculated from **homogeneous**, interacting electron gas
- Exchange-correlation potential

$$v_{xc}(\rho(\mathbf{r})) = \left[ \frac{\partial}{\partial \rho} \{ \rho \varepsilon_{xc}(\rho) \} \right]_{\rho=\rho(\mathbf{r})}$$

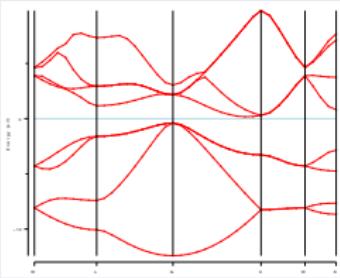


# Kohn and Sham, 1965: Local Density Approximation

## Limitations and Beyond

- LDA **exact** for homogeneous electron gas (within QMC)
- **Spatial variation of  $\rho$  ignored**
  - include  $\nabla\rho(\mathbf{r}), \dots$
  - Generalized Gradient Approximation (GGA)
- **Self-interaction cancellation in  $v_{Hartree} + v_x$  violated**

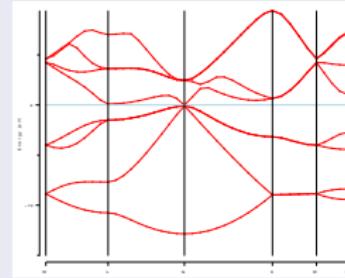
Si



## Bandgaps

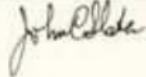
- Si, exp: 1.11 eV
- Si, GGA: 0.57 eV
- Ge, exp: 0.67 eV
- Ge, GGA: 0.09 eV

Ge



# Muffin-Tin Approximation

John C. Slater

A handwritten signature of John C. Slater's name.

## Full Potential

$$v_\sigma(\mathbf{r}) : \begin{cases} \text{spherical symmetric near nuclei} \\ \text{flat outside the atomic cores} \end{cases}$$

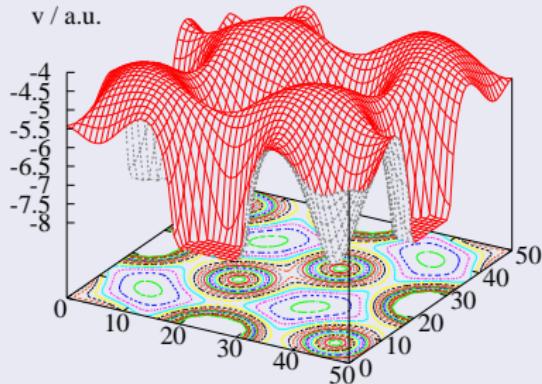
## Muffin-Tin Approximation

$$v_\sigma^{MT}(\mathbf{r}) = \begin{cases} \text{spherical symmetric in spheres} \\ \text{constant in interstitial region} \end{cases}$$


# Muffin-Tin Approximation

Full Potential

(FeS<sub>2</sub>)



Muffin-Tin Potential

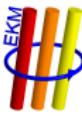


# Muffin-Tin Approximation

## Wave Function

- ① solve Schrödinger's eq.  
→ **partial waves**
- ② match partial waves  
→ basis functions,  
„augmented“ partial waves
- ③ use to expand  
→ **wave function**

## Muffin-Tin Potential



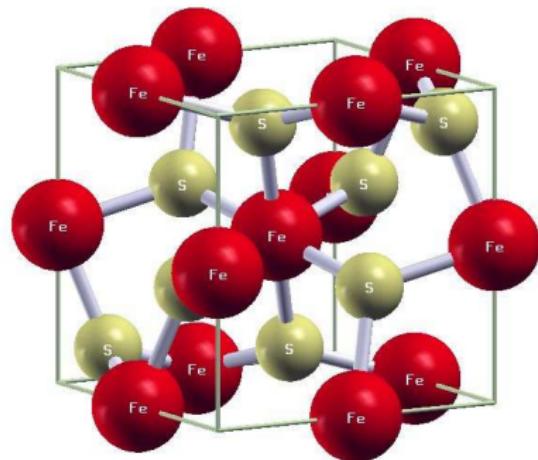
# Muffin-Tin Approximation

## Flavors

- Muffin-Tin Approximation: touching spheres
- Atomic Sphere Approximation: space-filling spheres
  - interstitial region formally removed
  - only numerical functions in spheres
  - minimal basis set ( $s, p, d$ )
    - very high computational efficiency →  $\mathcal{O}(\text{ASA})$  speed!!!
  - makes potential more realistic
  - systematic error in total energybad!



# Iron Pyrite: FeS<sub>2</sub>



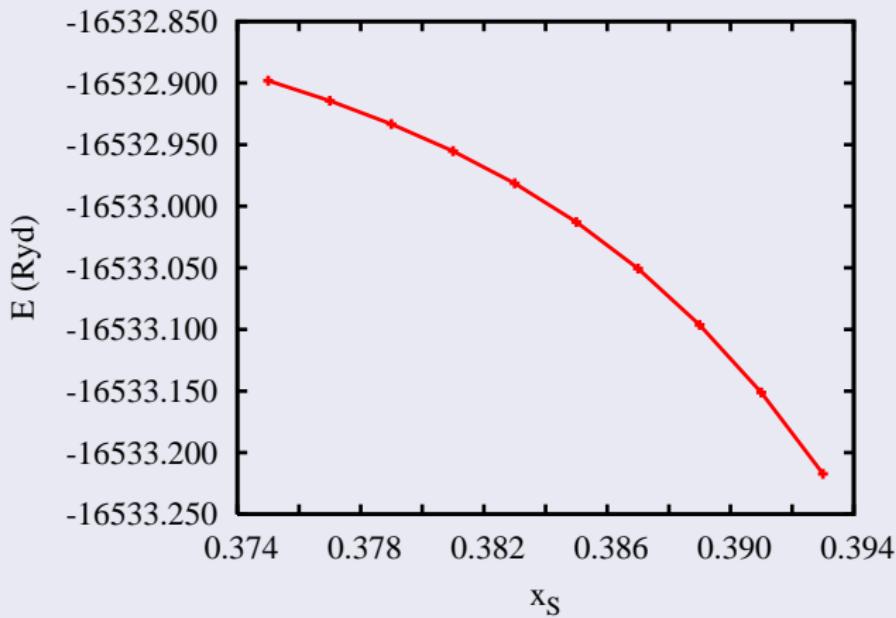
## Pyrite

- $P\bar{a}3$  ( $T_h^6$ )
- $a = 5.4160 \text{ \AA}$
- “NaCl structure” sublattices occupied by
  - iron atoms
  - sulfur pairs
- sulfur pairs  $\parallel \langle 111 \rangle$  axes
- $x_S = 0.38484$
- rotated FeS<sub>6</sub> octahedra



# FeS<sub>2</sub>: Structure Optimization

ASA<sup>+</sup> Code



# Basic Principles of the Full-Potential ASW Method

## Steps to be Taken

- remove total energy error due to overlap of atomic spheres
  - reintroduce non-overlapping muffin-tin spheres
  - restore interstitial region



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- find representation of electron density and full potential
  - inside muffin-tin spheres
  - in the interstitial region



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  - inside muffin-tin spheres
    - use spherical-harmonics expansions
  - in the interstitial region



# Basic Principles of the Full-Potential ASW Method

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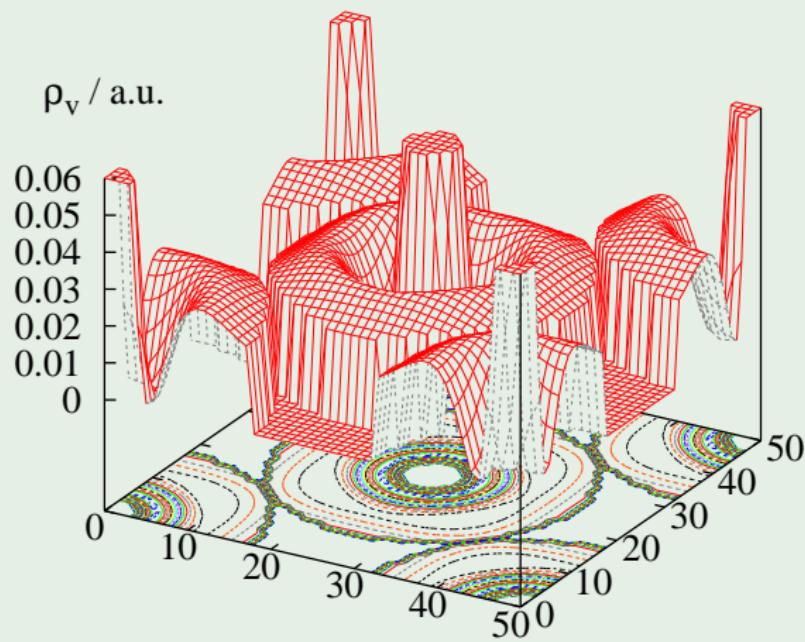
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- find representation of electron density and full potential
- find representation of products of the wave function
- find representation of products of the basis functions
  - inside muffin-tin spheres
    - use spherical-harmonics expansions
  - in the interstitial region
    - no exact spherical-wave representation available!



# From Wave Functions to Electron Density

## Density inside MT-Spheres

(AI)



# From Wave Functions to Electron Density

## Products of Spherical Waves in Interstitial Region

- expand in **spherical waves**
  - would be efficient
  - coefficients/integrals not known analytically
  - Methfessel, 1988:  
match values and slopes at MT-sphere surfaces



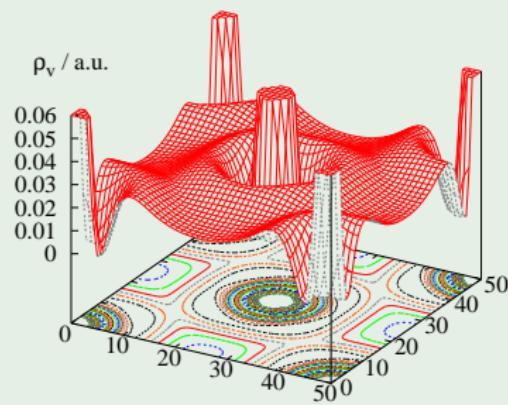
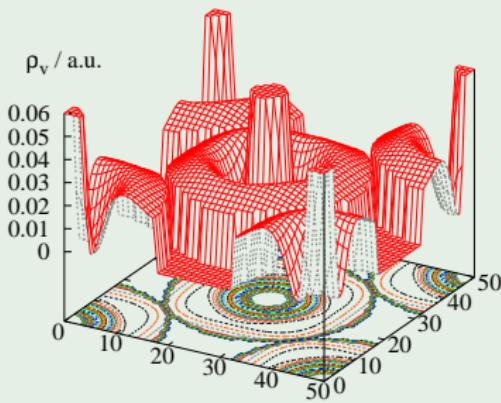
# From Wave Functions to Electron Density

## Products of Spherical Waves in Interstitial Region

- expand in **spherical waves**
  - match values and slopes at **MT-sphere** surfaces

## Density from Value/Slope Matching at MT-Radii

(AI)



# Comparison of Approaches

Ole K. Andersen

1975

- ASA geometry used for basis functions  
→ minimal basis set
- ASA geometry used for density and potential  
→ error in total energy

good!

bad!



# Comparison of Approaches

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- ASA geometry used for basis functions  
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- ASA geometry used for density and potential  
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good!

bad!

Michael S. Methfessel

1988

- MT geometry used for density and potential  
→ accurate total energy
- MT geometry used for basis functions  
→ large basis set

good!

bad!



# Comparison of Approaches

Ole K. Andersen 1975

- ASA geometry used for basis functions good!
- ASA geometry used for density and potential bad!

Michael S. Methfessel 1988

- MT geometry used for density and potential good!
- MT geometry used for basis functions bad!

present approach 2006

- ASA geometry used for basis functions  
→ minimal basis set →  $\mathcal{O}(\text{ASA})$  speed great!
- MT geometry used for density and potential  
→ accurate total energy great!

# Implementation: Augmented Spherical Wave Method

0th Generation ASW (Williams, Kübler, Gelatt, 1970s)

PRB **19**, 6094 (1979)

1st Generation (VE, 1990s)

- new implementation (accurate, stable, portable)  
VE, Int. J. Quantum Chem. **77**, 1007 (2000)  
VE, Lect. Notes Phys. **719** (Springer, 2007)
- xAnderson convergence acceleration scheme  
VE, J. Comput. Phys. **124**, 271 (1996)
- all LDA- and GGA-parametrizations
- still based on atomic-sphere approximation  
VE, Höck, PRB **57**, 12727 (1998)

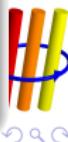
# Implementation: Augmented Spherical Wave Method

## 2nd Generation ASW (VE, 2000s)

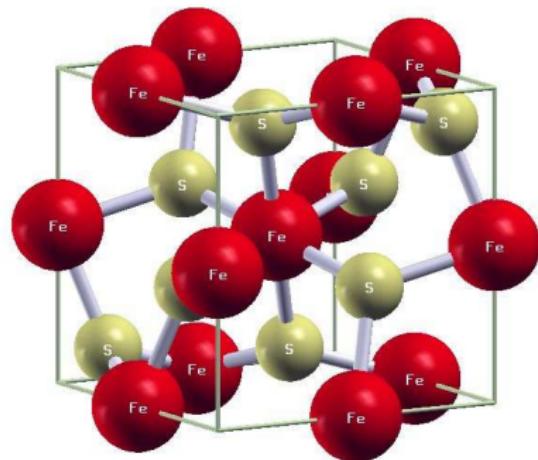
- based on 1st generation code
- full-potential ASW method
  - electron densities, spin densities
  - electric field gradients
  - elastic properties, phonon spectra
- optical properties
  - based on linear-response theory
  - direct calculation of  $\Re\sigma$  and  $\Im\sigma$
  - no Kramers-Kronig relations needed
- transport properties, thermoelectrics
- LDA+U method
  - all „flavors“ for double-counting terms (AMF, FLL, DFT)

at  $\mathcal{O}(\text{ASA})$  speed!

VE, Lect. Notes Phys. (2nd ed., Springer, 2011)



# Iron Pyrite: FeS<sub>2</sub>



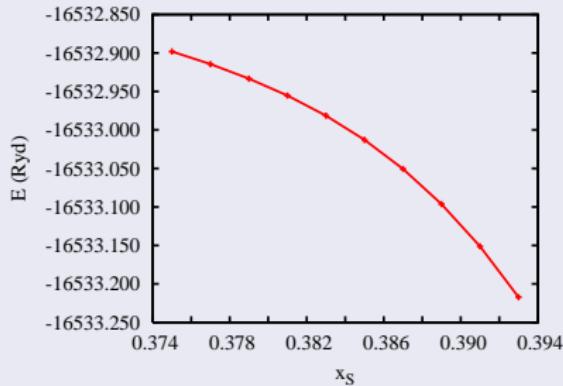
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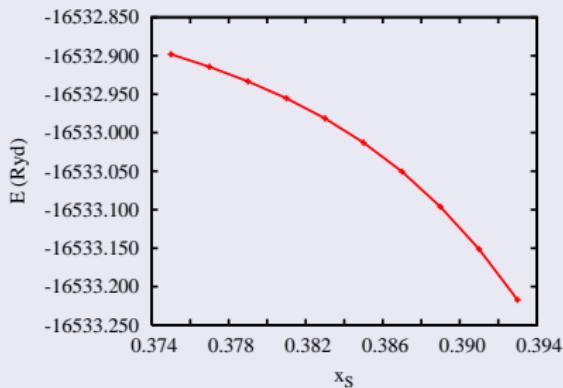
# FeS<sub>2</sub>: Structure Optimization

## ASA<sup>+</sup> Code

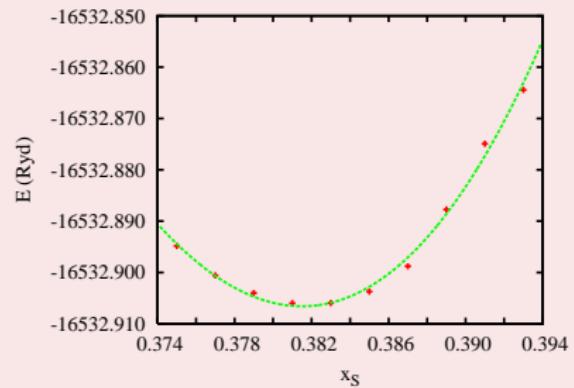


# FeS<sub>2</sub>: Structure Optimization

ASA<sup>+</sup> Code



Full-Potential Code

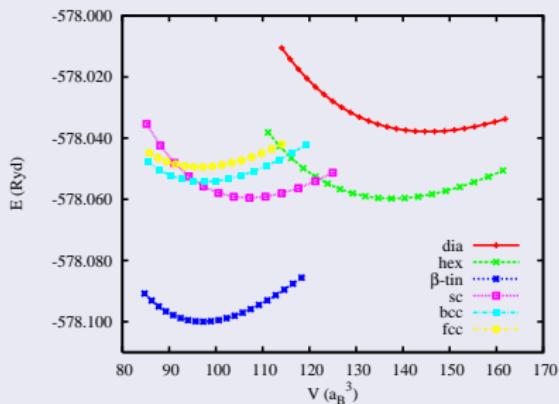


at  $\mathcal{O}(\text{ASA})$  speed!



# Phase Stability in Silicon

ASA<sup>+</sup> Code

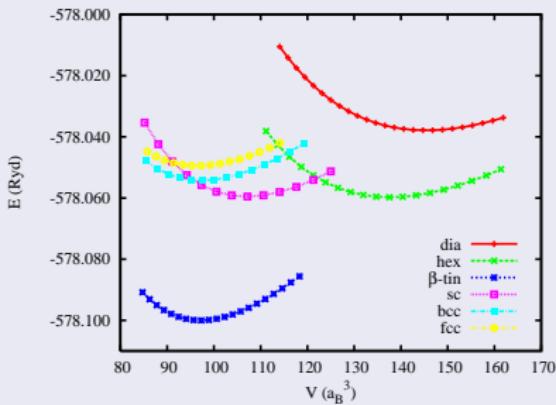


Bad

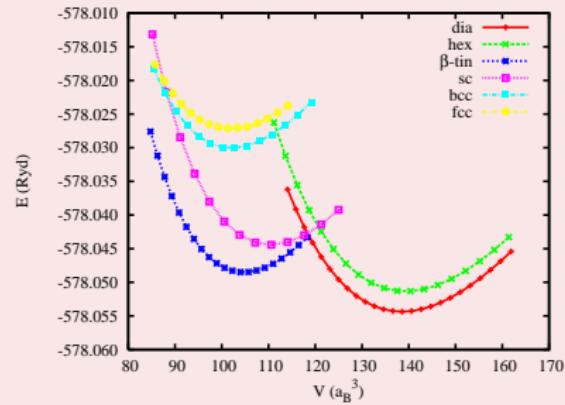
- $\beta$ -tin structure most stable # nature (diamond structure)

# Phase Stability in Silicon

## ASA<sup>+</sup> Code



## Full-Potential Code



New!

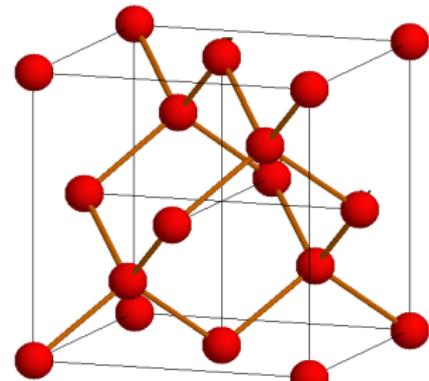
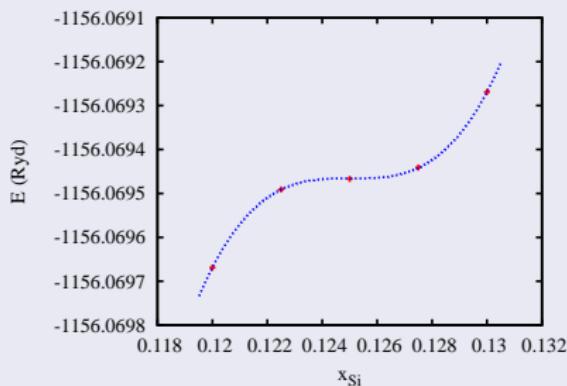
at  $\mathcal{O}(\text{ASA})$  speed!

- diamond structure most stable
- pressure induced phase transition to  $\beta$ -tin structure



# LTO( $\Gamma$ )-Phonon in Silicon

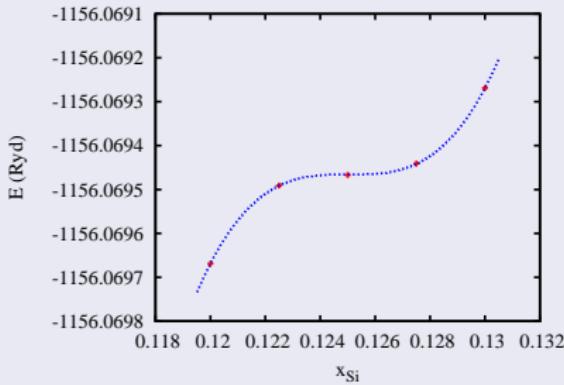
ASA<sup>+</sup> Code



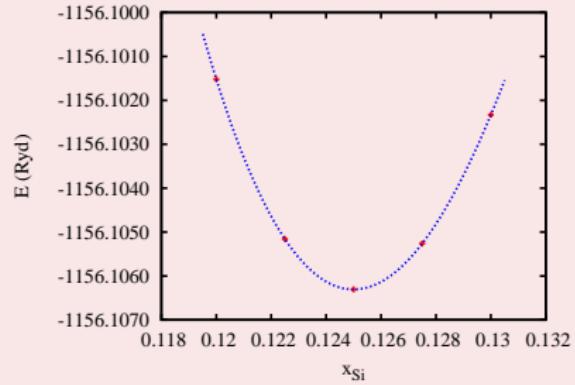
Bad

- no stable Si position # nature



LTO( $\Gamma$ )-Phonon in SiliconASA<sup>+</sup> Code

## Full-Potential Code



New!

at  $\mathcal{O}(\text{ASA})$  speed!

- phonon frequency:  $f_{\text{calc}} = 15.34 \text{ THz}$  ( $f_{\text{exp}} = 15.53 \text{ THz}$ )



# Outline

## 1 Quantum Mechanics

- Density Functional Theory
- Full-Potential ASW Method

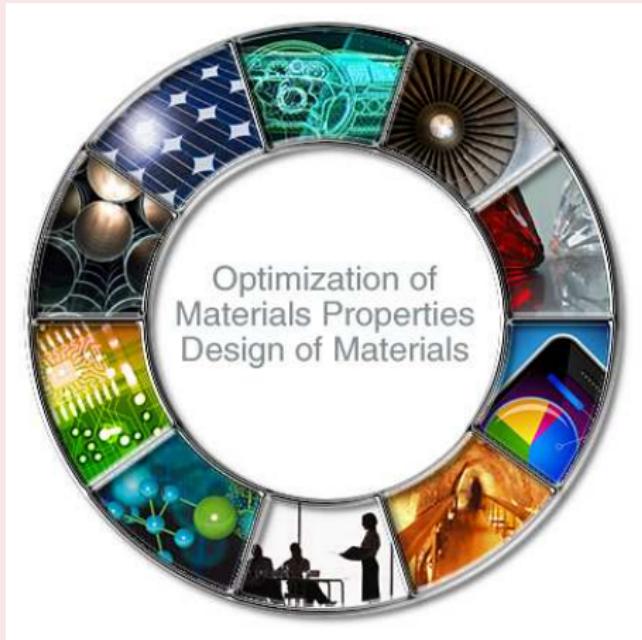
## 2 „Materials Design“



# Industrial Applications

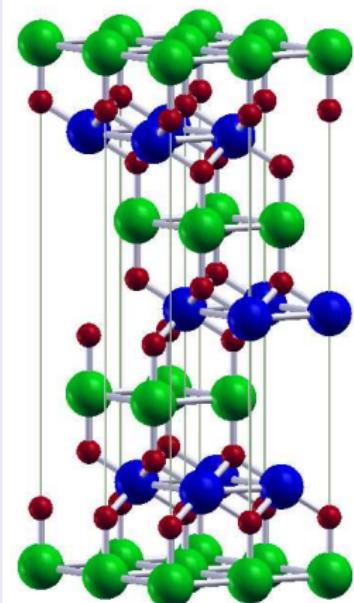
## Computational Materials Engineering

- Automotive
- Energy & Power Generation
- Aerospace
- Steel & Metal Alloys
- Glass & Ceramics
- Electronics
- Display & Lighting
- Chemical & Petrochemical
- Drilling & Mining



# Delafoossites: $\text{ABO}_2$

## Delafoosite Structure



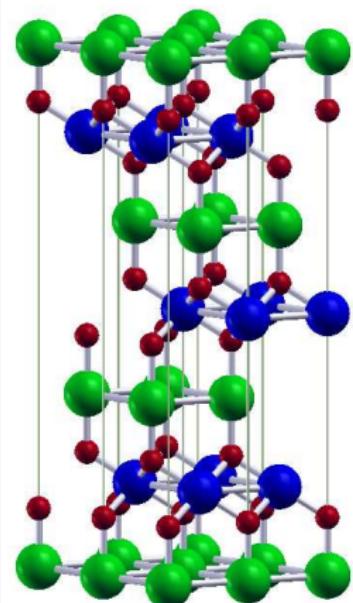
## Building Blocks

- rhombohedral lattice
- triangular **A**-atom layers
- **BO**<sub>2</sub> sandwich layers
- B-atoms octahedrally coordinated
- linear **O**—**A**—**O** bonds



# Delafoossites: $\text{ABO}_2$

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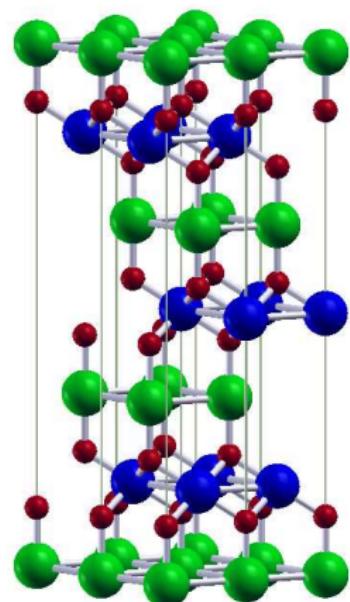
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- $\text{BO}_2$  sandwich layers
- B-atoms octahedrally coordinated
- linear  $\text{O}-\text{A}-\text{O}$  bonds

## Issues

- dimensionality
- geometric frustration
- play chemistry

# Delafoossites: $\text{ABO}_2$

## Delafoosite Structure



## Prototype Materials

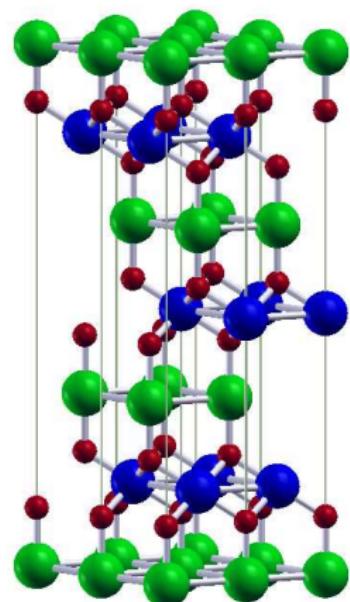
- $\text{CuFeO}_2$ ,  $\text{CuCrO}_2$
- $\text{CuCoO}_2$ ,  $\text{CuRhO}_2$
- $\text{CuAlO}_2$ ,  $\text{CuGaO}_2$ ,  $\text{CuInO}_2$ , ...
- $\text{PdCrO}_2$ ,  $\text{PdCoO}_2$ ,  $\text{PdRhO}_2$ ,  $\text{PtCoO}_2$

## Properties

- semiconductors, AF interactions,  
(distorted) triangular
- non-magn. semicond., thermopower
- wide-gap semicond., p-type TCO
- very good metals, high anisotropy

# Delafoossites: $\text{ABO}_2$

## Delafoosite Structure



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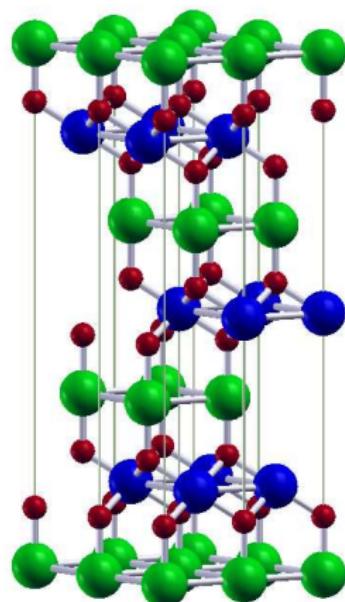
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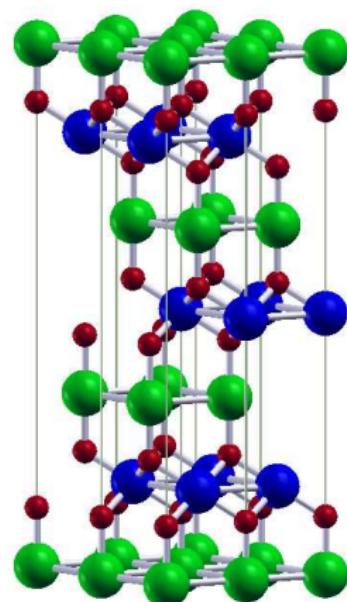
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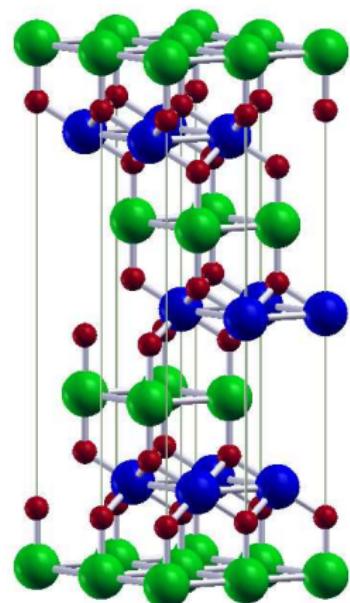
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# PdCoO<sub>2</sub> and PtCoO<sub>2</sub>

## Delafoseite Structure



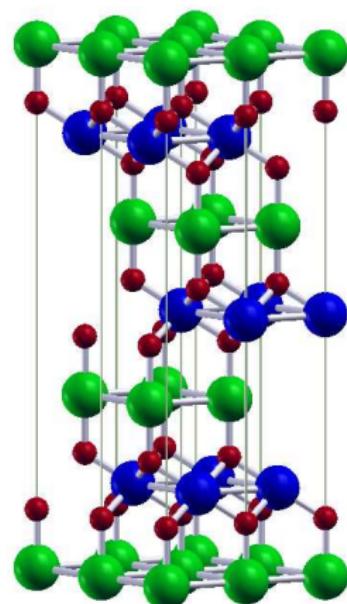
## Experimental Results

- very low resistivity
- anisotropy ratio  $\approx 200$
- PES: only Pd 4d states at  $E_F$
- PES/IPES:  $E_F$  in shallow DOS minimum
  - high thermopower on doping?



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- PES/IPES:  $E_F$  in shallow DOS minimum
  - high thermopower on doping?

## Open Issues

role of Pd 4d, Co 3d, and O 2p orbitals?

# Structure Optimization in PdCoO<sub>2</sub>

## Structural Data

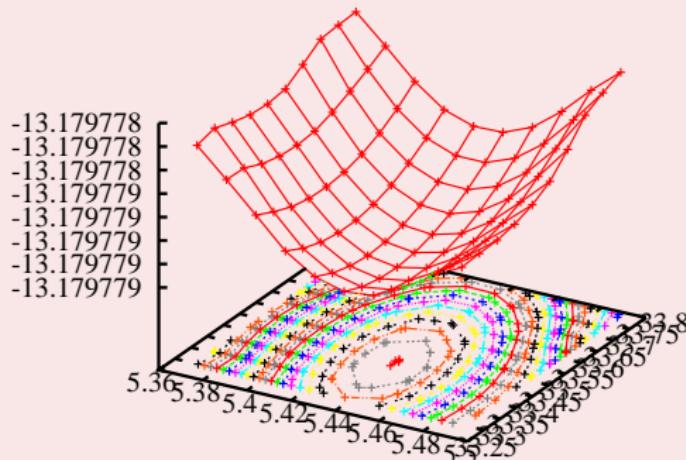
### experiment

- $a = 2.83 \text{ \AA}$
- $c = 17.743 \text{ \AA}$
- $z_0 = 0.1112$

### theory

- $a = 2.8767 \text{ \AA}$
- $c = 17.7019 \text{ \AA}$
- $z_0 = 0.1100$

## Total energy surface

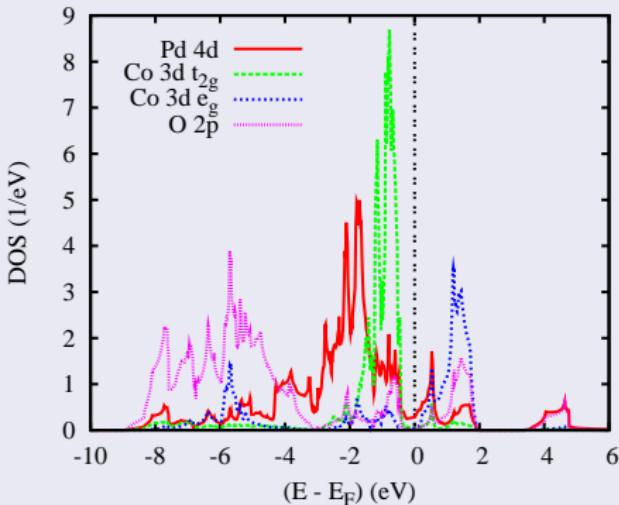


VE, R. Frésard, A. Maignan, Chem. Mat. **20**, 2370 (2008)



# Electronic Properties of PdCoO<sub>2</sub>

## Partial Densities of States



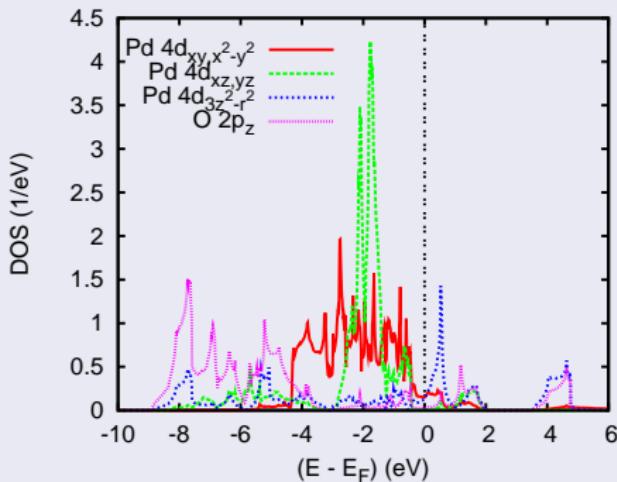
## Results

- Co 3d-O 2p hybridization
- CoO<sub>6</sub> octahedra:  
 $\text{Co } 3d \Rightarrow t_{2g} \text{ and } e_g$
- Co 3d<sup>6</sup> (Co<sup>3+</sup>) LS
- Pd 4d<sup>9</sup> (Pd<sup>1+</sup>)
- Co 3d, O 2p: very small DOS at E<sub>F</sub>

VE, R. Frésard, A. Maignan, Chem. Mat. **20**, 2370 (2008)

# Electronic Properties of PdCoO<sub>2</sub>

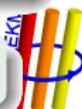
## Partial Densities of States



## Results

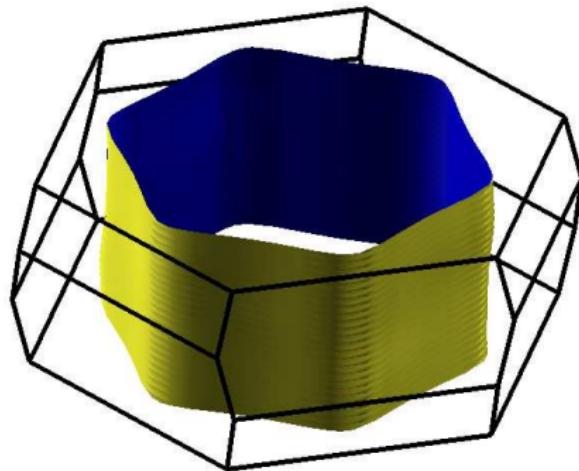
- broad Pd  $d_{xy,x^2-y^2}$  bands
  - short in-plane Pd-Pd distance
- non-bonding Pd  $d_{xz,yz}$  bands
- strong Pd  $4d_{3z^2-r^2}$ -O  $2p$  hybridization
- states at E<sub>F</sub>:  
Pd  $d_{xy,x^2-y^2}$ ,  $d_{3z^2-r^2}$

VE, R. Frésard, A. Maignan, Chem. Mat. **20**, 2370 (2008)



# Electronic Properties of PdCoO<sub>2</sub>

## Fermi Surface



## Results

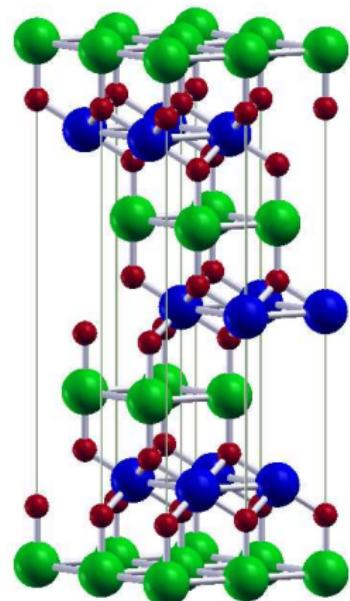
- quasi-2D
- single band crossing  $E_F$
- but: bands below  $E_F$  disperse along  $\Gamma$ -A

VE, R. Frésard, A. Maignan, Chem. Mat. **20**, 2370 (2008)



# CuFeO<sub>2</sub>

## Delafoseite Structure



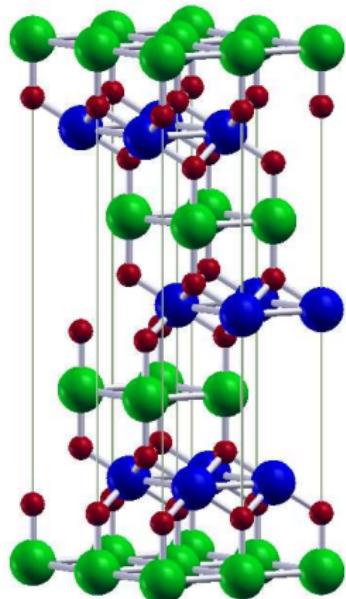
### Basics

- semiconductor
- AF interactions
- triangular lattice



# CuFeO<sub>2</sub>

## Delafoseite Structure



### Basics

- semiconductor
- AF interactions
- triangular lattice

### Open Issues

- frustration vs. long-range order
- role of Cu 3d orbitals?
- role of Fe 3d and O 2p orbitals?



# CuFeO<sub>2</sub>

## Previous Neutron Data

- $T_{N_1} = 16\text{ K}$ ,  $T_{N_2} = 11\text{ K}$
- $\Theta_{CW} = -90\text{ K}$
- magnetic supercells
- no structural distortion
- $m_{\text{Fe}^{3+}} = 4.4\mu_B$

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## Band Calculations

- rhombohedral structure
- $m_{\text{Fe}} = 0.9\mu_B$ ,  $m_{\text{Fe}} = 3.8\mu_B$
- $E_g = 0$  in LDA, GGA
- $\ddagger$  PES, XES



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## New Neutron Data

- magnetic supercells
- monoclinic structure below 4K



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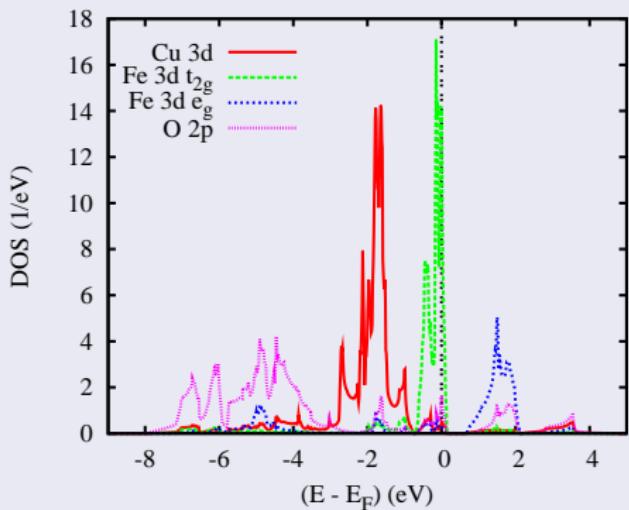
## Open Issues

- spin-state of Fe?
- influence of monoc. structure?



# Electronic Properties of CuFeO<sub>2</sub>

## Partial Densities of States



## Results

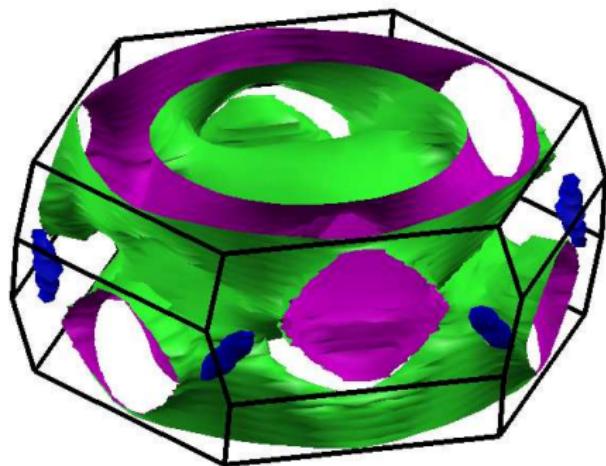
- Fe 3d-O 2p hybridization
- FeO<sub>6</sub> octahedra:  
 $\text{Fe } 3d \Rightarrow t_{2g} \text{ and } e_g$
- Cu 4d<sup>10</sup> (Cu<sup>1+</sup>)
- Fe 3d  $t_{2g}$ 
  - sharp peak at  $E_F$

VE, R. Frésard, A. Maignan, PRB **78**, 052402 (2008)



# Electronic Properties of CuFeO<sub>2</sub>

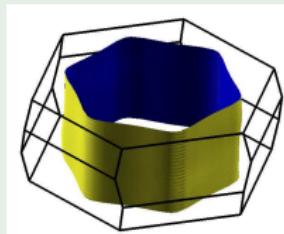
## Fermi Surface



## Results

- strongly 3D

## FS PdCoO<sub>2</sub>



VE, R. Frésard, A. Maignan, PRB **78**, 052402 (2008)



# Magnetic Properties of CuFeO<sub>2</sub>

Total Energies (mRyd/f.u.), Magn. Moms. ( $\mu_B$ ), Band Gaps (eV)

structure	magn. order	$\Delta E$	$m_{\text{Fe}}$	$m_{\text{O}}$	$E_g$
rhomb.	spin-deg.	0.0			-
rhomb.	ferro (LS)	-16.7	1.03	-0.02	-
rhomb.	ferro (IS)	-12.0	2.02	-0.02	-
rhomb.	ferro (HS)	-19.2	3.73	0.21	-

VE, R. Frésard, A. Maignan, PRB **78**, 052402 (2008)

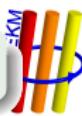


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rhomb.	ferro (HS)	-19.2	3.73	0.21	-
monoc.	spin-deg.	-6.0			-
monoc.	ferro (LS)	-21.5	1.04	-0.02	-
monoc.	ferro (IS)	-19.0	2.08	-0.02	-
monoc.	ferro (HS)	-32.0	3.62	0.19	-

VE, R. Frésard, A. Maignan, PRB **78**, 052402 (2008)

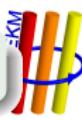


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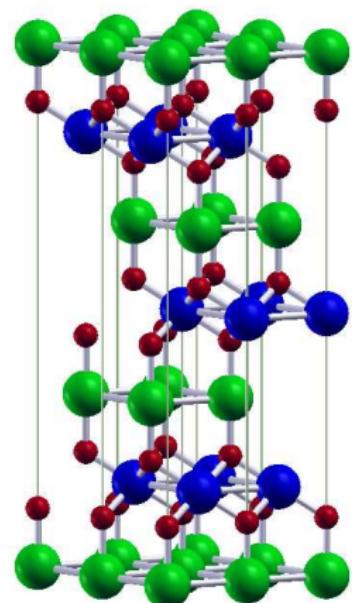
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monoc.	ferro (IS)	-19.0	2.08	-0.02	-
monoc.	ferro (HS)	-32.0	3.62	0.19	-
monoc.	antiferro	-46.0	$\pm 3.72$	$\pm 0.08$	0.05

VE, R. Frésard, A. Maignan, PRB **78**, 052402 (2008)



# CuRhO<sub>2</sub>

## Delafoseite Structure

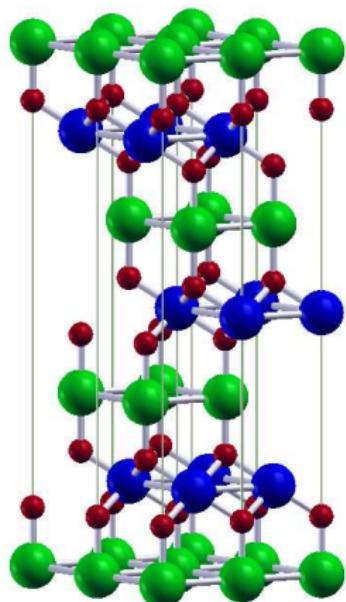


## Experimental Findings

- semiconductor
- high thermopower on hole doping
  - $\text{Rh}^{3+} \longrightarrow \text{Mg}^{2+}$  up to 12%
- high  $T$ -independent power factor

# CuRhO<sub>2</sub>

## Delafoseite Structure



## Experimental Findings

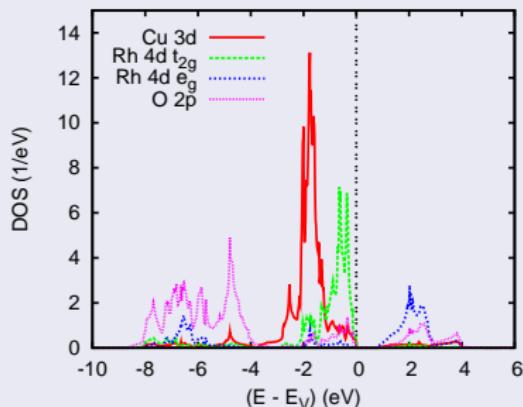
- semiconductor
- high thermopower on hole doping
  - $\text{Rh}^{3+} \longrightarrow \text{Mg}^{2+}$  up to 12%
- high  $T$ -independent power factor

## Open Issues

- origin of high thermopower
- role of Cu 3d orbitals?
- role of Rh 4d and O 2p orbitals?

# Electronic Properties of CuRhO<sub>2</sub>

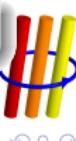
## Partial Densities of States



## Results

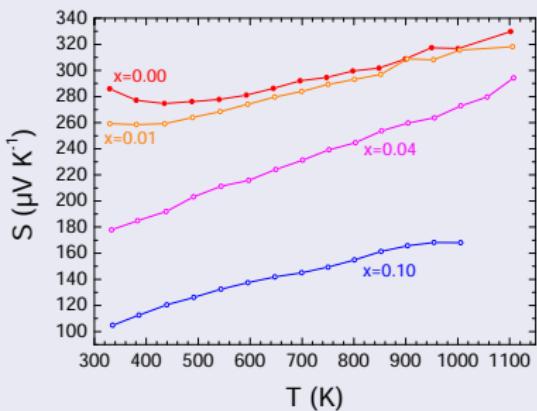
- Rh 4d-O 2p hybridization
- RhO<sub>6</sub> octahedra:  
 $\text{Rh } 4d \Rightarrow t_{2g} \text{ and } e_g$
- $E_g \approx 0.75 \text{ eV}$
- Cu 4d<sup>10</sup> ( $\text{Cu}^{1+}$ )
- electronic structure:  
strongly 3D

A. Maignan, VE et al., PRB **80**, 115103 (2009)

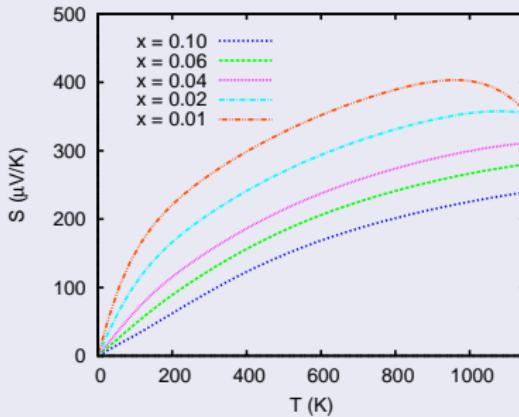


# Thermoelectric Power of CuRh<sub>1-x</sub>Mg<sub>x</sub>O<sub>2</sub>

## Experiment



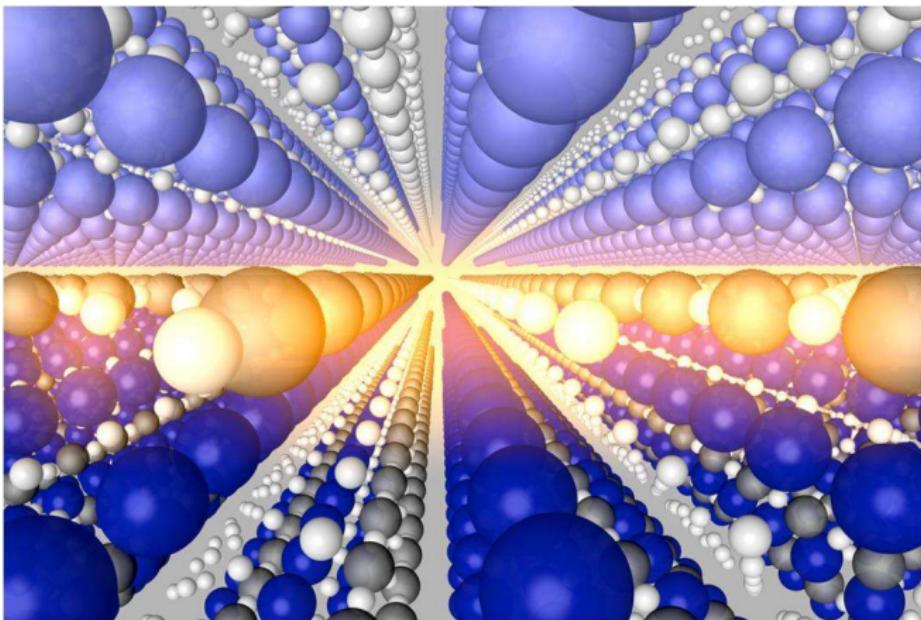
## Theory: $S_{xx}$



A. Maignan, VE et al., PRB **80**, 115103 (2009)

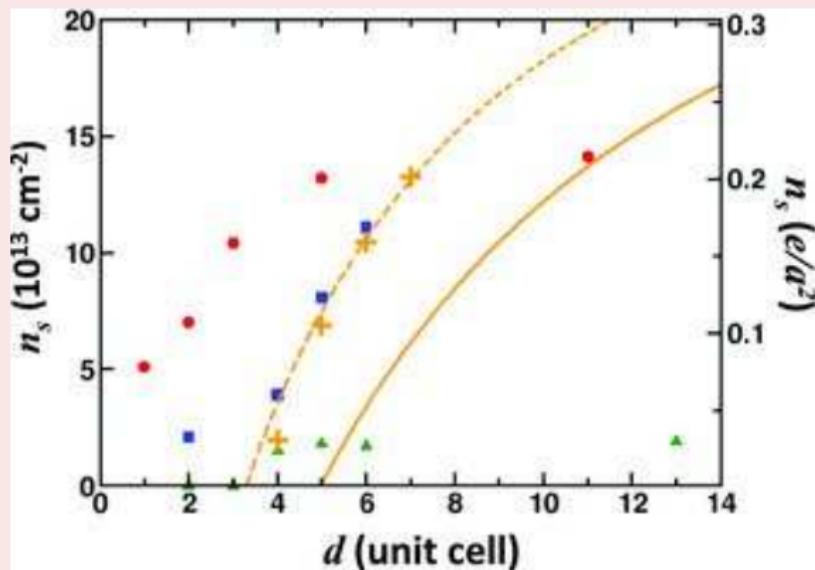


# 2D Electron Gas at LaAlO<sub>3</sub>-SrTiO<sub>3</sub> Interface



# 2D Electron Gas at LaAlO<sub>3</sub>-SrTiO<sub>3</sub> Interface

## Insulator-Metal Transition



Chen, Kolpak, Ismail-Beigi, Adv. Mater. **22**, 2881 (2010)

# Slab Calculations for the LaAlO<sub>3</sub>-SrTiO<sub>3</sub> Interface



## Structural setup of calculations

- central region: 5 layers SrTiO<sub>3</sub>, TiO<sub>2</sub>-terminated
- sandwiches: 2 to 5 layers LaAlO<sub>3</sub>, AlO<sub>2</sub> surface
- vacuum region  $\approx 20 \text{ \AA}$
- inversion symmetry
- lattice constant of SrTiO<sub>3</sub> from GGA (3.944 Å)



# Slab Calculations for the LaAlO<sub>3</sub>-SrTiO<sub>3</sub> Interface



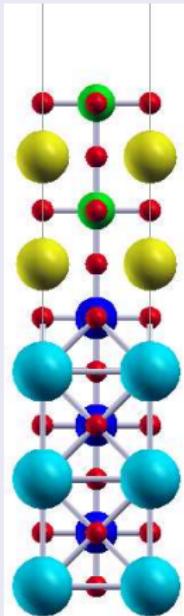
## Calculational method

- Vienna Ab Initio Simulation Package (VASP)
- GGA-PBE
- Steps:
  - 1 optimization of SrTiO<sub>3</sub> lattice constant
  - 2 slab calculations
    - full relaxation of all atomic positions
    - $5 \times 5 \times 1$   $\mathbf{k}$ -points
    - $\Gamma$ -centered  $\mathbf{k}$ -mesh
    - Methfessel-Paxton BZ-integration

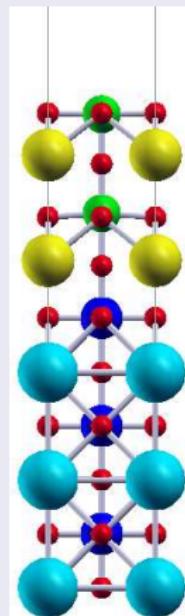


# Slab Calculations for the LaAlO<sub>3</sub>-SrTiO<sub>3</sub> Interface

Ideal



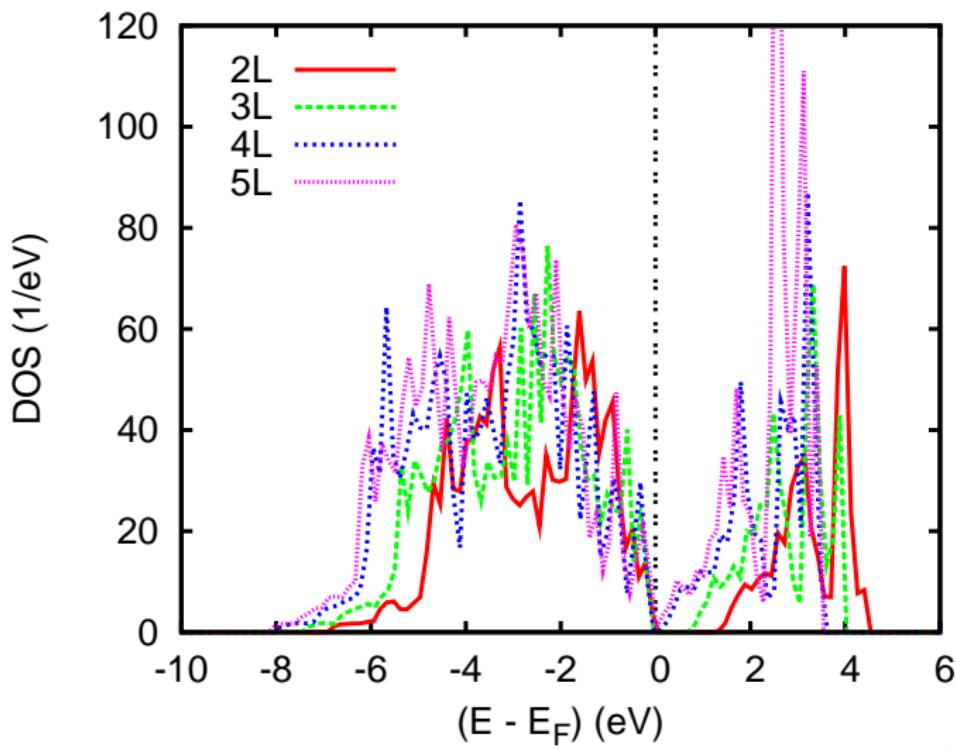
Optimized



## Structural relaxation

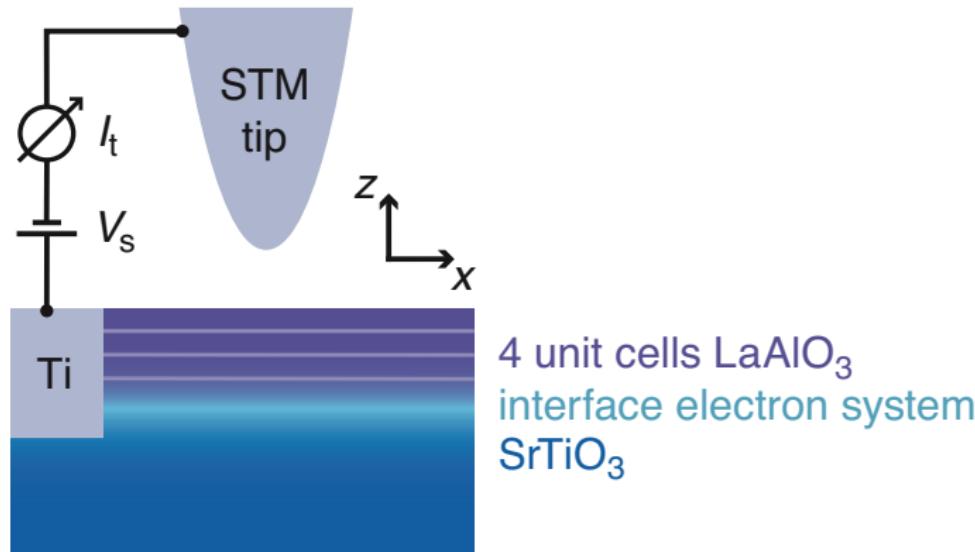
- AlO<sub>2</sub> surface layers
  - strong inward relaxation
  - weak buckling
- LaO layers
  - strong buckling
- AlO<sub>2</sub> subsurface layers
  - buckling
- TiO<sub>2</sub> interface layers
  - small outward relaxation

# Slab Calculations for the LaAlO<sub>3</sub>-SrTiO<sub>3</sub> Interface



# Tunneling Spectroscopy of LaAlO<sub>3</sub>-SrTiO<sub>3</sub> Interface

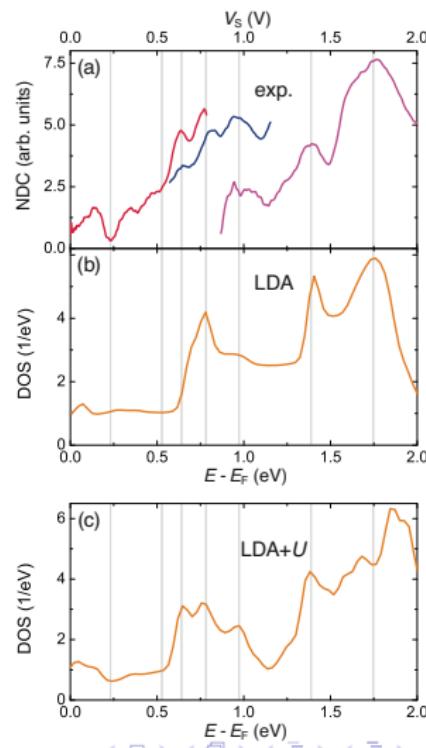
What is the origin of the 2-DEG?  
Intrinsic mechanism or defect-doping?



M. Breitschaft *et al.*, PRB **81**, 153414 (2010)

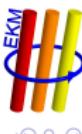
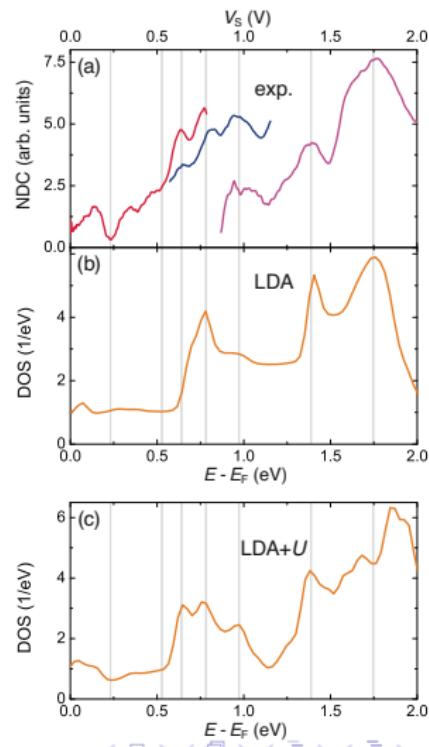
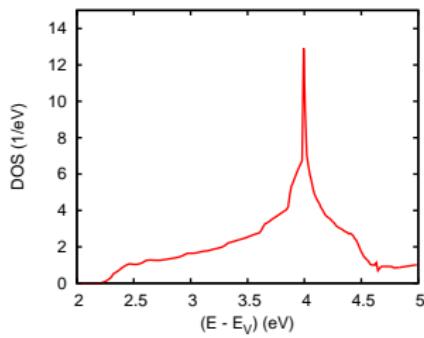
# Tunneling Spectroscopy of LaAlO<sub>3</sub>-SrTiO<sub>3</sub> Interface

- 4uc LaAlO<sub>3</sub> on SrTiO<sub>3</sub>, tunneling data
- 4uc LaAlO<sub>3</sub> on SrTiO<sub>3</sub>, LDA calculations, DOS of interface Ti
- 4uc LaAlO<sub>3</sub> on SrTiO<sub>3</sub>, LDA+U calculations, DOS of interface Ti

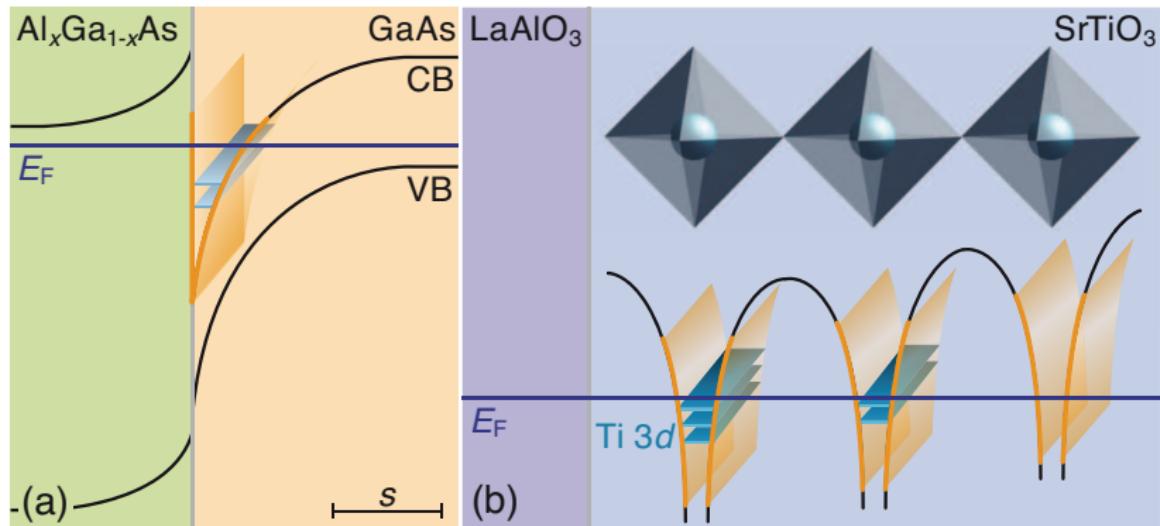


# Tunneling Spectroscopy of LaAlO<sub>3</sub>-SrTiO<sub>3</sub> Interface

- bulk SrTiO<sub>3</sub>,  
LDA calculations,  
conduction band DOS



# “2D Electron Liquid State” at LaAlO<sub>3</sub>-SrTiO<sub>3</sub> Interface



M. Breitschaft *et al.*, PRB **81**, 153414 (2010)



# Critical review of the Local Density Approximation

## Limitations and Beyond

- Self-interaction cancellation in  $v_{Hartree} + v_x$  violated
- Repair using exact Hartree-Fock exchange functional  
→ class of hybrid functionals

- PBE0

$$E_{xc}^{PBE0} = \frac{1}{4}E_x^{HF} + \frac{3}{4}E_x^{PBE} + E_c^{PBE}$$

- HSE03, HSE06

$$E_{xc}^{HSE} = \frac{1}{4}E_x^{HF,sr,\mu} + \frac{3}{4}E_x^{PBE,sr,\mu} + E_x^{PBE,Ir,\mu} + E_c^{PBE}$$

based on decomposition of Coulomb kernel

$$\frac{1}{r} = S_\mu(r) + L_\mu(r) = \frac{\operatorname{erfc}(\mu r)}{r} + \frac{\operatorname{erf}(\mu r)}{r}$$

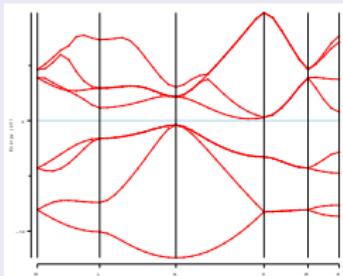


# Critical review of the Local Density Approximation

## Limitations and Beyond

- Self-interaction cancellation in  $v_{Hartree} + v_x$  violated
- Repair using exact Hartree-Fock exchange functional  
→ class of hybrid functionals

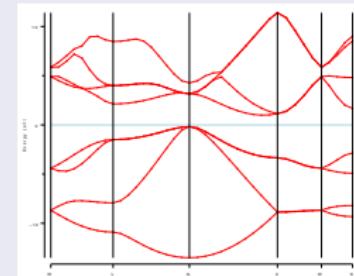
GGA



Si bandgap

- exp: 1.11 eV
- GGA: 0.57 eV
- HSE: 1.15 eV

HSE

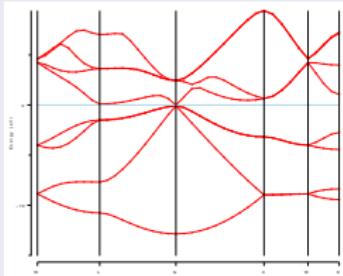


# Critical review of the Local Density Approximation

## Limitations and Beyond

- Self-interaction cancellation in  $v_{Hartree} + v_x$  violated
- Repair using exact Hartree-Fock exchange functional  
→ class of hybrid functionals

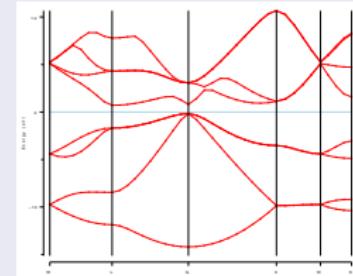
GGA



Ge bandgap

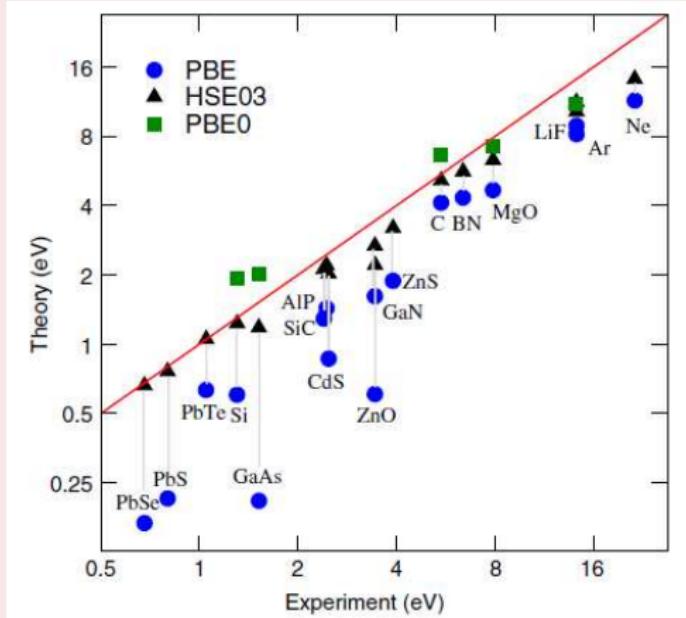
- exp: 0.67 eV
- GGA: 0.09 eV
- HSE: 0.66 eV

HSE



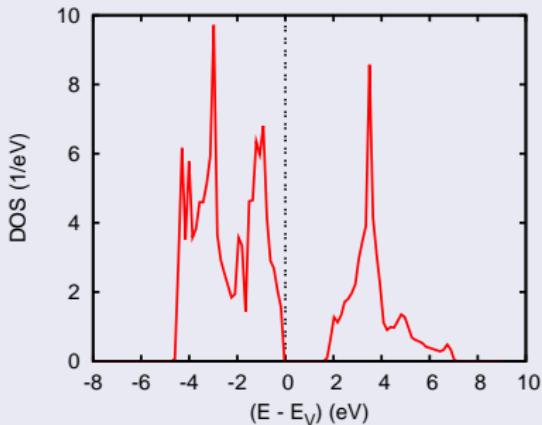
# Critical review of the Local Density Approximation

## Calculated vs. experimental bandgaps



# SrTiO<sub>3</sub>

GGA



Bandgap

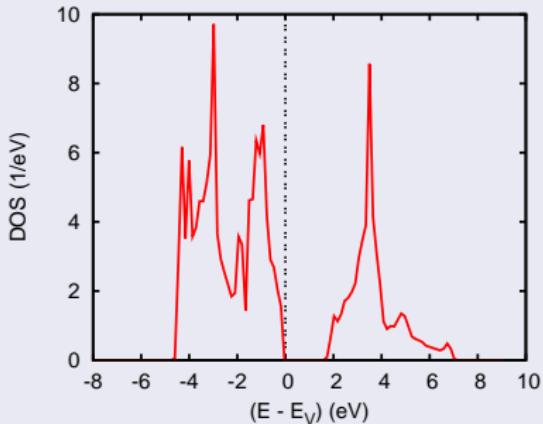
GGA:  $\approx 1.6$  eV,

exp.: 3.2 eV

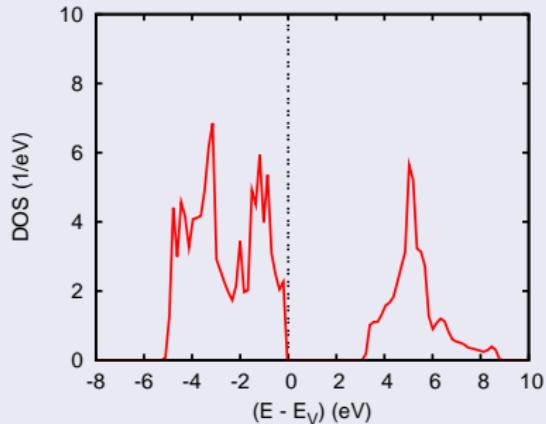


# SrTiO<sub>3</sub>

GGA



HSE



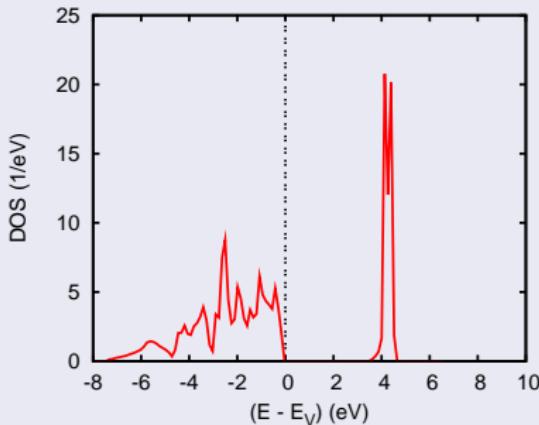
## Bandgap

GGA:  $\approx 1.6 \text{ eV}$ , HSE:  $\approx 3.1 \text{ eV}$ , exp.:  $3.2 \text{ eV}$



# LaAlO<sub>3</sub>

GGA



Bandgap

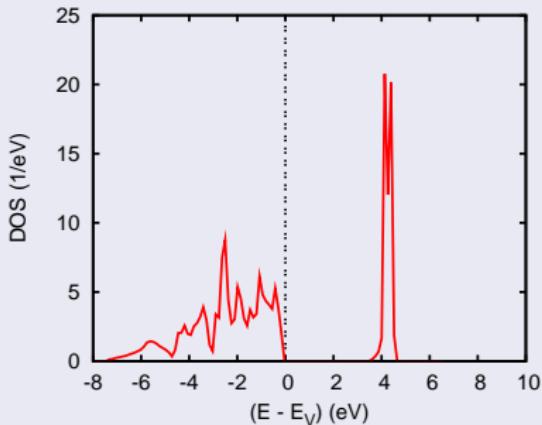
GGA:  $\approx 3.5$  eV,

exp.: 5.6 eV

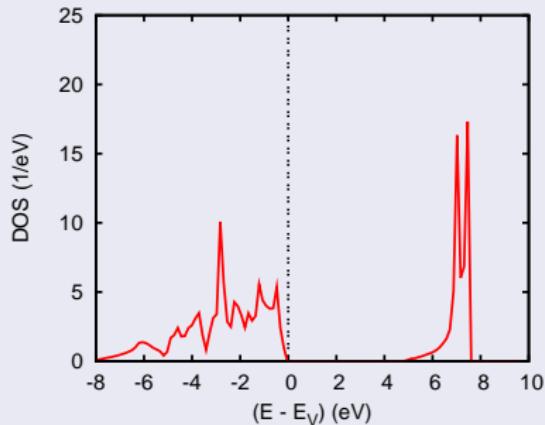


# LaAlO<sub>3</sub>

GGA



HSE



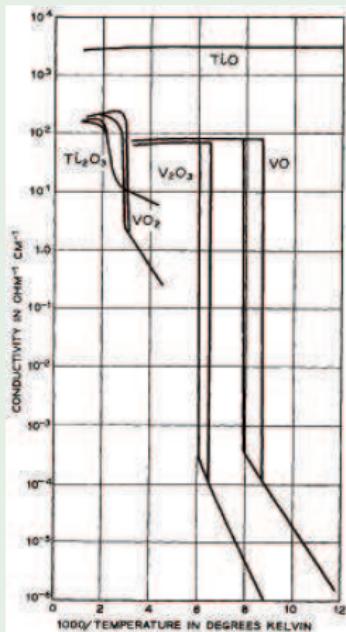
## Bandgap

GGA:  $\approx 3.5$  eV, HSE:  $\approx 5.0$  eV, exp.: 5.6 eV



# Metal-Insulator Transition of VO<sub>2</sub>

Morin, PRL 1959



## Metal-Insulator Transitions (MIT)

- VO<sub>2</sub> ( $d^1$ )
  - 1st order, 340 K,  $\Delta\sigma \approx 10^4$
  - rutile  $\rightarrow$  M<sub>1</sub> (monoclinic)
- V<sub>2</sub>O<sub>3</sub> ( $d^2$ )
  - 1st order, 170 K,  $\Delta\sigma \approx 10^6$
  - corundum  $\rightarrow$  monoclinic
  - paramagn.  $\rightarrow$  AF order

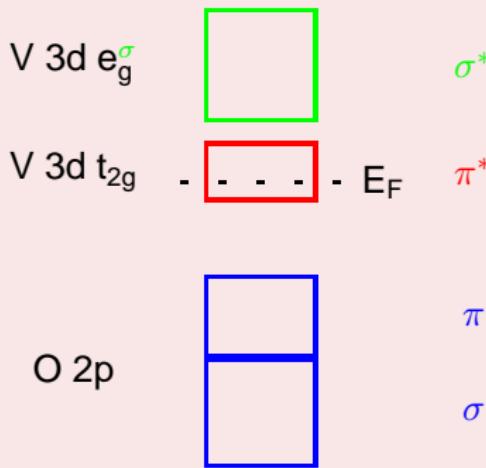
## Origin of the MIT???

- Structural Changes?
- Electron Correlations?



# Metal-Insulator Transition of VO<sub>2</sub>

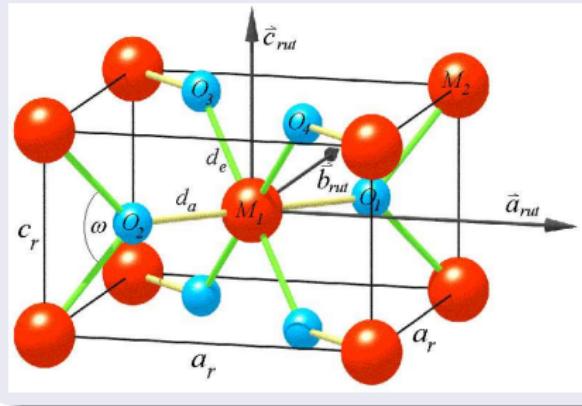
## Octahedral Coordination



- V 3d-O 2p hybridization
  - $\sigma$ ,  $\sigma^*$  ( $p-de_g^\sigma$ )
  - $\pi$ ,  $\pi^*$  ( $p-dt_{2g}$ )

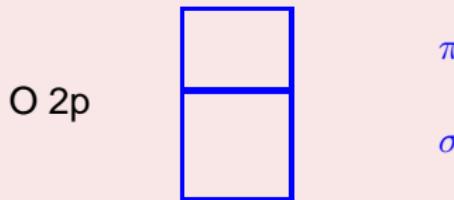
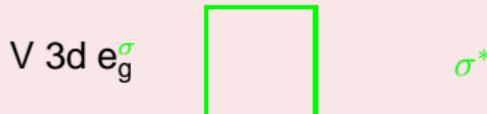
## Rutile Structure

- simple tetragonal
- P4<sub>2</sub>/mnm (D<sub>4h</sub><sup>14</sup>)



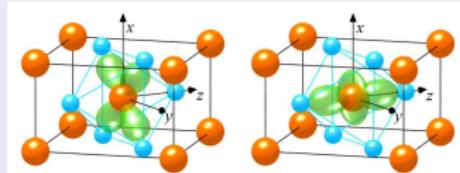
# Metal-Insulator Transition of VO<sub>2</sub>

## Octahedral Coordination

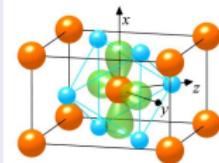
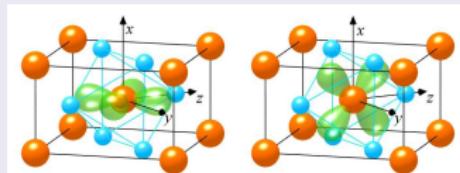


- V 3d-O 2p hybridization
  - $\sigma$ ,  $\sigma^*$  ( $p-de_g^\sigma$ )
  - $\pi$ ,  $\pi^*$  ( $p-dt_{2g}$ )

## $e_g^\sigma$ Orbitals

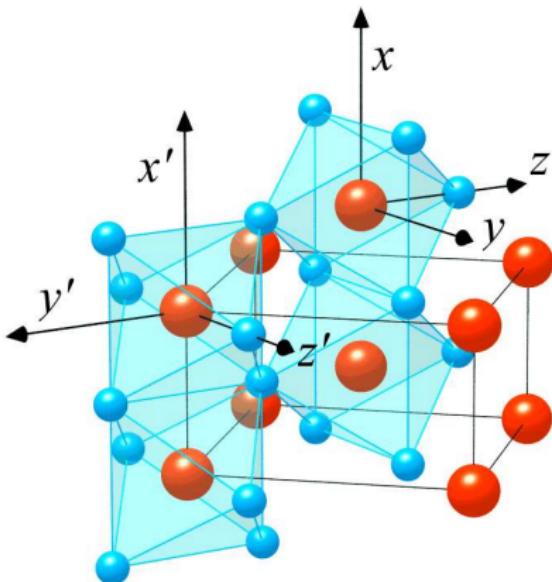


## $t_{2g}$ Orbitals



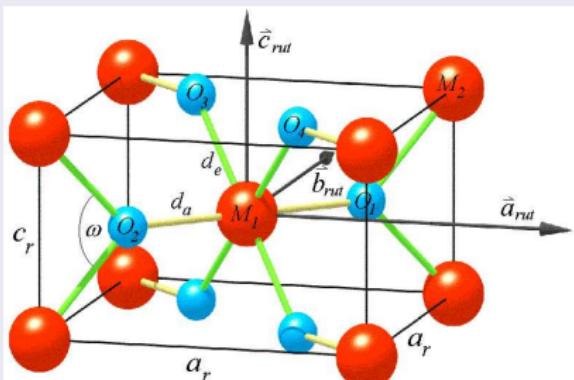
# Metal-Insulator Transition of VO<sub>2</sub>

## Octahedral Chains



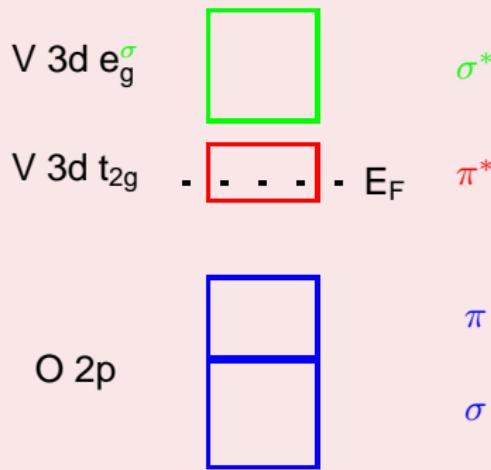
## Rutile Structure

- simple tetragonal
- P4<sub>2</sub>/mnm ( $D_{4h}^{14}$ )

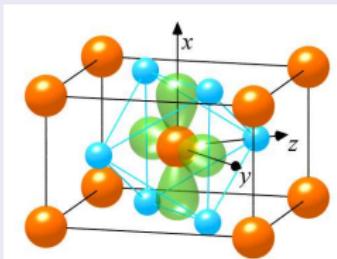
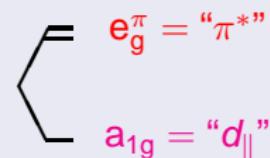
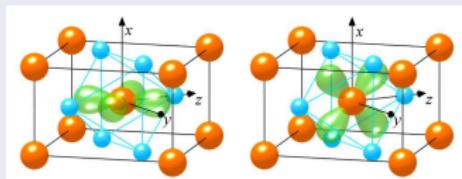


# Metal-Insulator Transition of VO<sub>2</sub>

## Octahedral Coordination

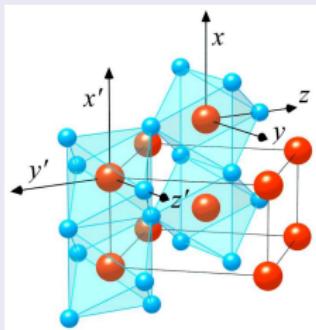


## $t_{2g}$ Orbitals

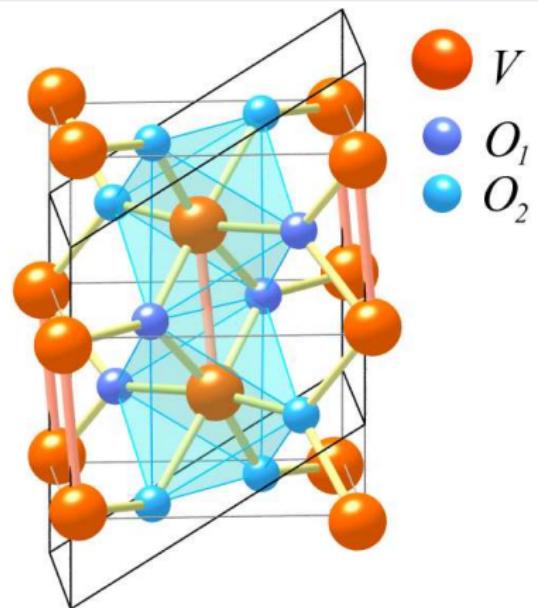


# Metal-Insulator Transition of VO<sub>2</sub>

## Rutile Structure



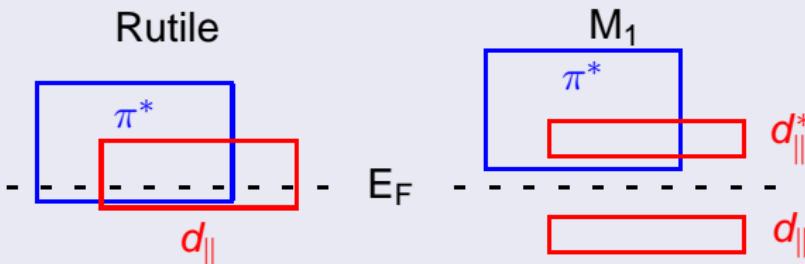
## M<sub>1</sub>-Structure



## Structural Changes

- V-V dimerization  $\parallel c_R$
- antiferroelectric displacement  $\perp c_R$

# Metal-Insulator Transition of VO<sub>2</sub>

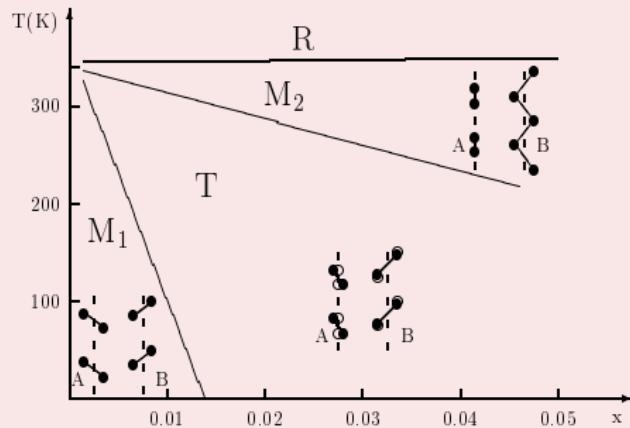


- Goodenough, 1960-1972
    - metal-metal dimerization  $\parallel c_R \rightarrow$  splitting into  $d_{\parallel}$ ,  $d_{\perp}^*$
    - antiferroelectric displacement  $\perp c_R \rightarrow$  upshift of  $\pi^*$
  - Zylbersztein and Mott, 1975
    - splitting of  $d_{\parallel}$  by electronic correlations
    - upshift of  $\pi^*$  unscreened  $d_{\parallel}$  electrons



# Metal-Insulator Transition of VO<sub>2</sub>

## Other Phases



- doping with Cr, Al, Fe, Ga
- uniaxial pressure  $\parallel \langle 110 \rangle$

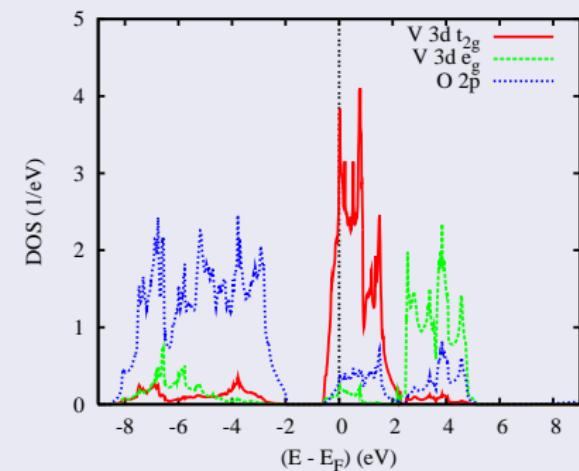
$\text{Cr}_x\text{V}_{1-x}\text{O}_2$   
Pouget, Launois, 1976



# Electronic Structure in Detail

## Rutile Structure

- molecular-orbital picture ✓
- octahedral crystal field  
 $\Rightarrow \text{V } 3d \ t_{2g}/e_g$
- V 3d–O 2p hybridization



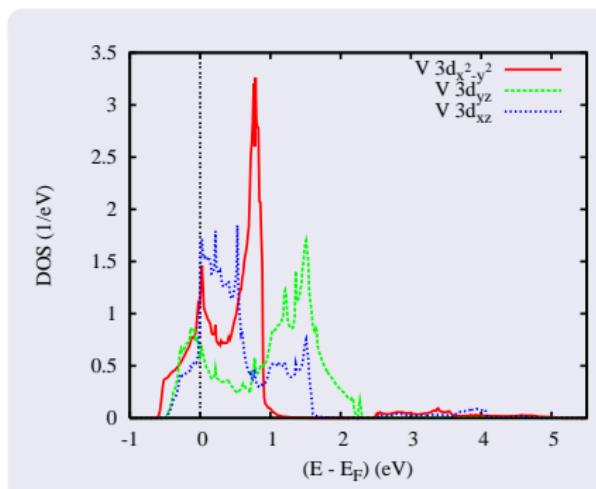
Ann. Phys. (Leipzig) 11, 650 (2002)



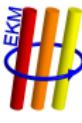
# Electronic Structure in Detail

## Rutile Structure

- molecular-orbital picture ✓
- octahedral crystal field  
 $\Rightarrow V\ 3d\ t_{2g}/e_g$
- $V\ 3d$ -O  $2p$  hybridization
- $t_{2g}$  at  $E_F$ :  $d_{x^2-y^2}$ ,  $d_{yz}$ ,  $d_{xz}$
- $n(d_{x^2-y^2}) \approx n(d_{yz}) \approx n(d_{xz})$

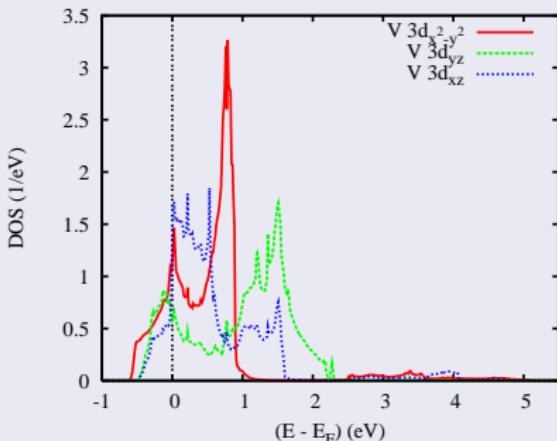


Ann. Phys. (Leipzig) 11, 650 (2002)

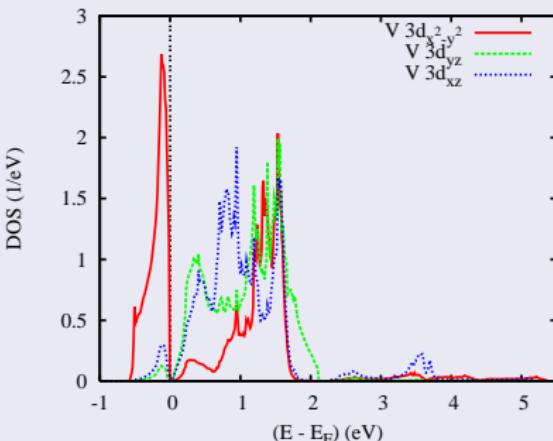


# Electronic Structure in Detail

## Rutile Structure



## M<sub>1</sub> Structure



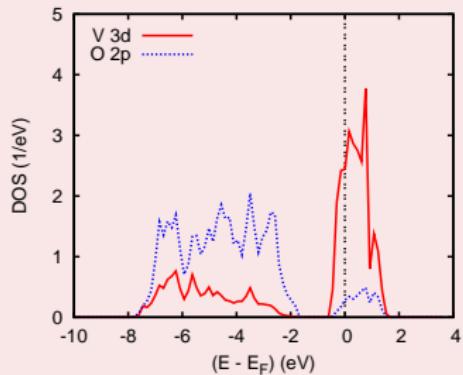
- bonding-antibonding splitting of  $d_{\parallel}$  bands
- energetical upshift of  $\pi^*$  bands  $\Rightarrow$  orbital ordering
- optical band gap on the verge of opening



# New Calculations: GGA vs. HSE

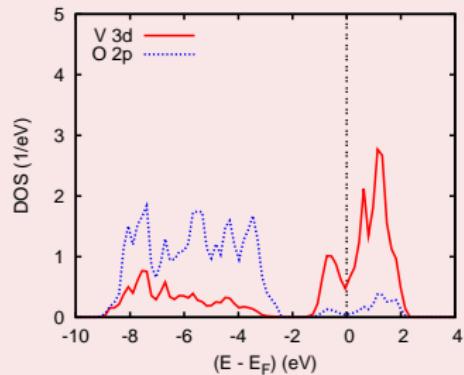
Rutile Structure

GGA



Rutile Structure

HSE



## Rutile Structure: GGA $\Rightarrow$ HSE

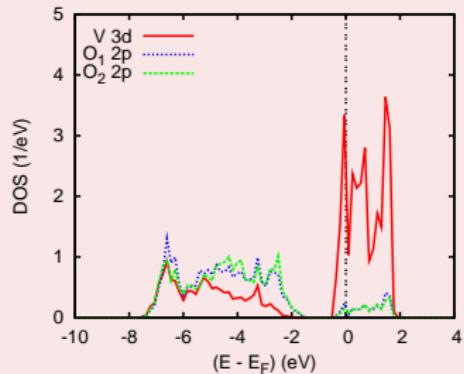
- broadening of O 2p and V 3d  $t_{2g}$ (!) bands
- splitting within V 3d  $t_{2g}$  bands



# New Calculations: GGA vs. HSE

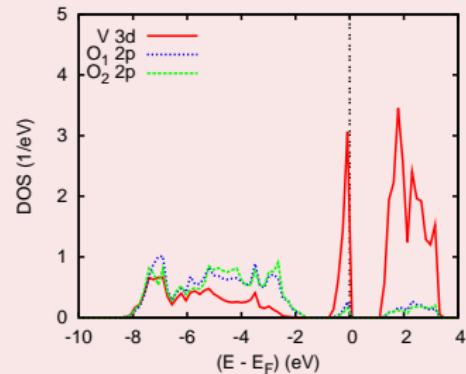
M<sub>1</sub> Structure

GGA



M<sub>1</sub> Structure

HSE

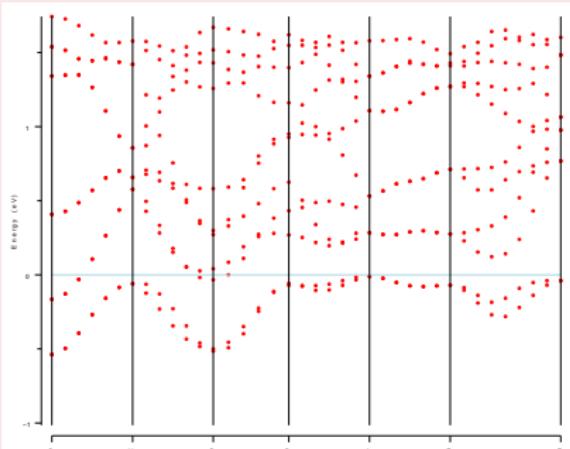


M<sub>1</sub> Structure: GGA  $\Rightarrow$  HSE

- splitting of  $d_{\parallel}$  bands, upshift of  $\pi^*$  bands
- optical bandgap of  $\approx 1$  eV

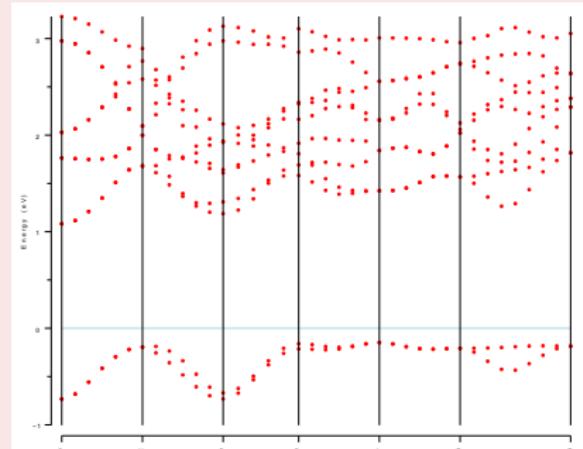
# New Calculations: GGA vs. HSE

M<sub>1</sub> Structure



GGA

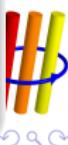
M<sub>1</sub> Structure



HSE

M<sub>1</sub> Structure: GGA  $\Rightarrow$  HSE

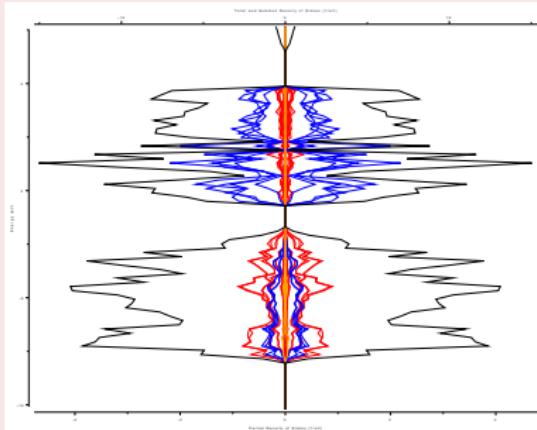
- splitting of  $d_{\parallel}$  bands, upshift of  $\pi^*$  bands
- optical bandgap of  $\approx 1$  eV



# New Calculations: GGA vs. HSE

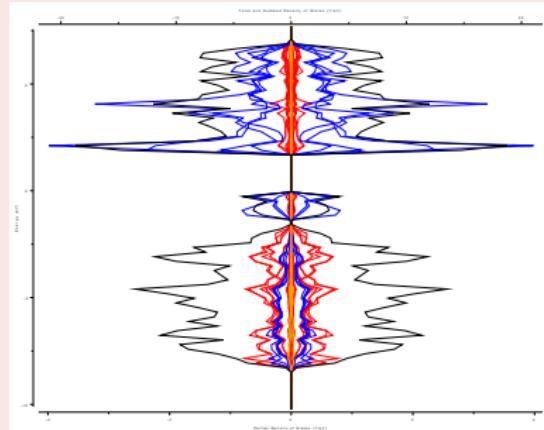
M<sub>2</sub> Structure

GGA



M<sub>2</sub> Structure

HSE



M<sub>2</sub> Structure: GGA  $\Rightarrow$  HSE

- localized magnetic moment of  $1 \mu_B$
- optical bandgap of  $\approx 1.6$  eV



# Unified Picture

## Rutile-Related Transition-Metal Dioxides

$\text{VO}_2$  ( $3d^1$ ),  $\text{NbO}_2$  ( $4d^1$ ),  $\text{MoO}_2$  ( $4d^2$ )  
( $\text{WO}_2$  ( $5d^2$ ),  $\text{TcO}_2$  ( $4d^3$ ),  $\text{ReO}_2$  ( $5d^3$ ))

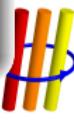
- instability against similar local distortions
  - metal-metal dimerization  $\parallel c_R$
  - antiferroelectric displacement  $\perp c_R$
- („accidental“) metal-insulator transition of the  $d^1$ -members

VE *et al.*, J. Phys.: CM **12**, 4923 (2000)

VE, Ann. Phys. **11**, 650 (2002)

VE, EPL **58**, 851 (2002)

J. Moosburger-Will *et al.*, PRB **79**, 115113 (2009)

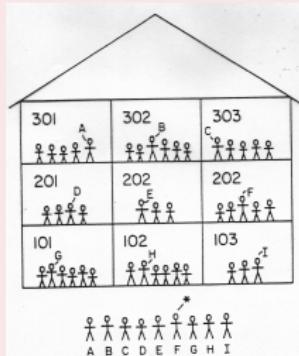


# Success Stories

## Basics

- DFT (exact, ground state)
- LDA, GGA, ...

## Percus-Levy partition



# Success Stories

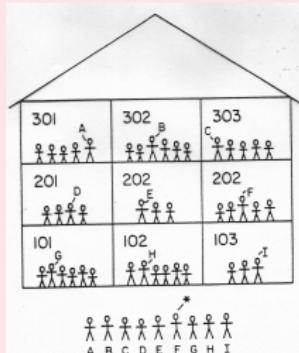
## Basics

- DFT (exact, ground state)
- LDA, GGA, ...

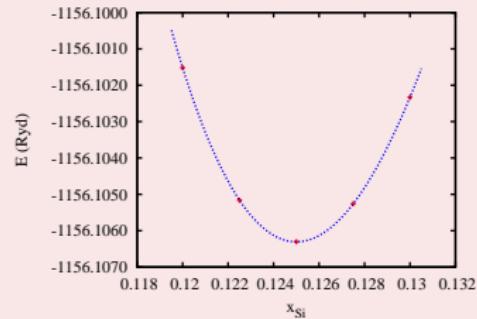
## Implementation

- Muffins and beyond
- Full-Potential ASW

## Percus-Levy partition



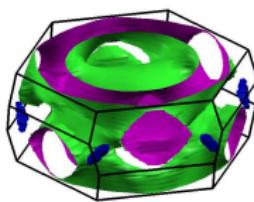
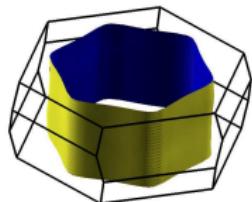
## Full-Potential Code



# Success Stories

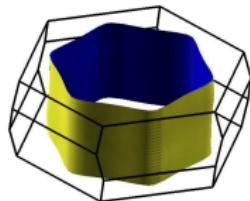
Delafoossites

2D → 3D

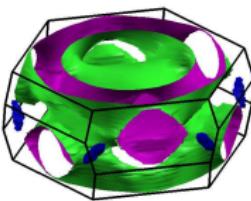


# Success Stories

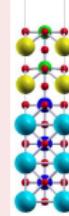
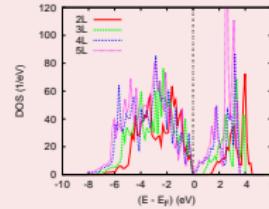
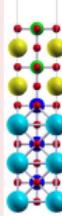
## Delafoossites



2D → 3D



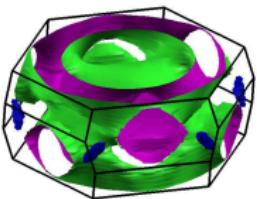
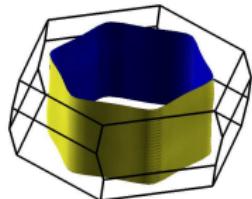
## LaAlO<sub>3</sub>/SrTiO<sub>3</sub>



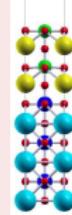
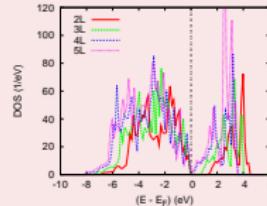
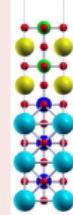
# Success Stories

## Delafoossites

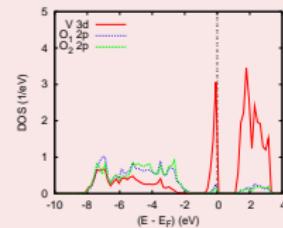
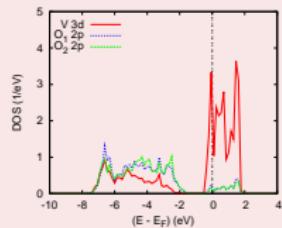
2D → 3D



## LaAlO<sub>3</sub>/SrTiO<sub>3</sub>

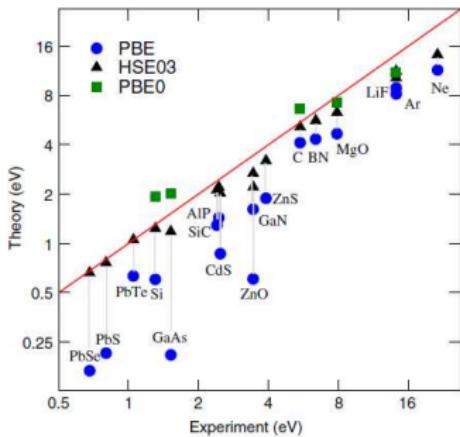


## Metal-Insulator Transitions in VO<sub>2</sub>

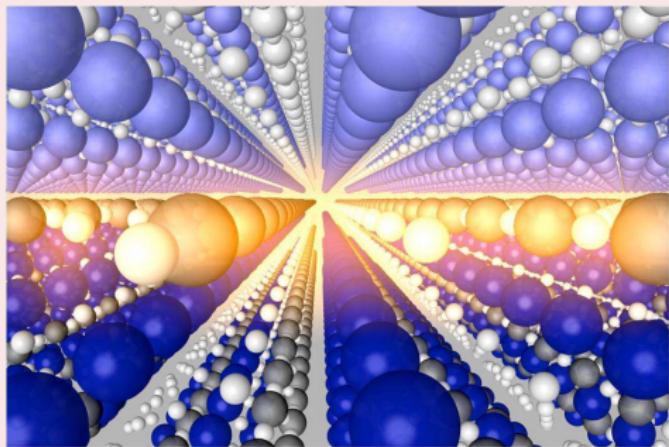


# Visions

## Methods



## Materials



# Acknowledgments

## Augsburg

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K.-H. Höck, S. Horn, R. Horny,  
T. Kopp, J. Kündel, J. Mannhart,  
J. Moosburger-Will, N. Pavlenko,  
W. Scherer, D. Vollhardt

## TRR 80



## Caen

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A. Maignan,  
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## Europe/USA

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P. Saxe, R. Windiks, W. Wolf



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Thank You for Your Attention!

